

# ISL6146

## Low Voltage OR-ing FET Controller

FN7667  
Rev 5.00  
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The [ISL6146](#) represents a family of OR-ing MOSFET controllers capable of OR-ing voltages from 1V to 18V. Together with suitably sized N-channel power MOSFETs, the ISL6146 increases power distribution efficiency when replacing a power OR-ing diode in high current applications. It provides gate drive voltage for the MOSFET(s) with a fully integrated charge pump.

The ISL6146 allows users to adjust with external resistor(s) the  $V_{OUT} - V_{IN}$  trip point, which adjusts the control sensitivity to system power supply noise. An open drain FAULT pin will indicate if a conditional or FET fault has occurred.

The ISL6146A and ISL6146B are optimized for very low voltage operation, down to 1V with an additional independent bias of 3V or greater.

The ISL6146C provides a voltage compliant mode of operation down to 3V with programmable undervoltage lock out and overvoltage protection threshold levels.

The ISL6146D and ISL6146E are like the ISL6146A and ISL6146B respectively, but do not have conduction state reporting via the fault output.

TABLE 1. KEY DIFFERENCES BETWEEN PARTS IN FAMILY

| PART NUMBER | KEY DIFFERENCES                                    |
|-------------|----------------------------------------------------|
| ISL6146A    | Separate BIAS and $V_{IN}$ with Active High Enable |
| ISL6146B    | Separate BIAS and $V_{IN}$ with Active Low Enable  |
| ISL6146C    | $V_{IN}$ with OVP/UVLO Inputs                      |
| ISL6146D    | ISL6146A without Conduction Monitor and Reporting  |
| ISL6146E    | ISL6146B without Conduction Monitor and Reporting  |

## Features

- OR-ing down to 1V and up to 20V with ISL6146A, ISL6146B, ISL6146D and ISL6146E
- Programmable voltage compliant operation with ISL6146C
- $V_{IN}$  hot swap transient protection rating to +24V
- High speed comparator provides fast  $<0.3\mu s$  turn-off in response to shorts on sourcing supply
- Fastest reverse current fault isolation with 6A turn-off current
- Very smooth switching transition
- Internal charge pump to drive N-channel MOSFET
- User programmable  $V_{IN} - V_{OUT}$  Vth for noise immunity
- Open-drain  $\overline{FAULT}$  output with delay
  - Short between any two of the OR-ing FET terminals
  - GATE voltage and excessive FET  $V_{DS}$
  - Power-good indicator (ISL6146C)
- MSOP and DFN package options

## Applications

- N+1 industrial and telecom power distribution systems
- Uninterruptable power supplies
- Low voltage processor and memory
- Storage and datacom systems

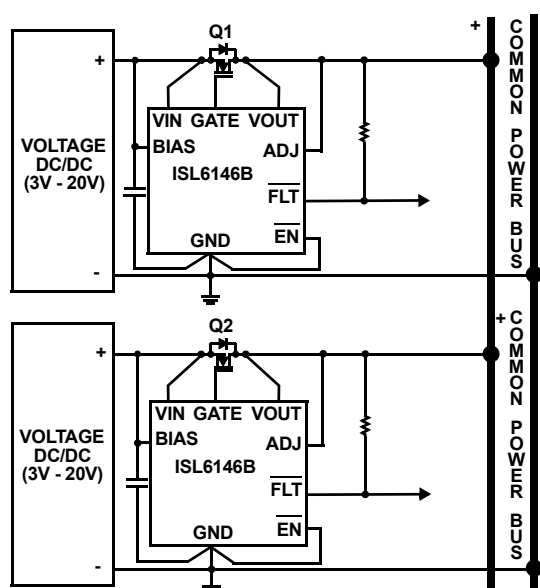


FIGURE 1. TYPICAL APPLICATION

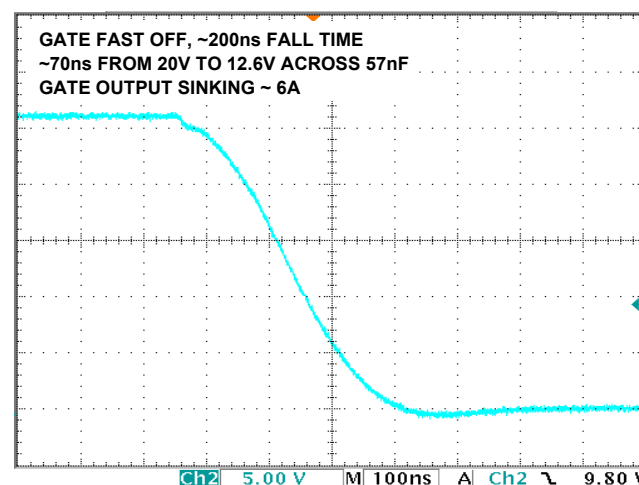


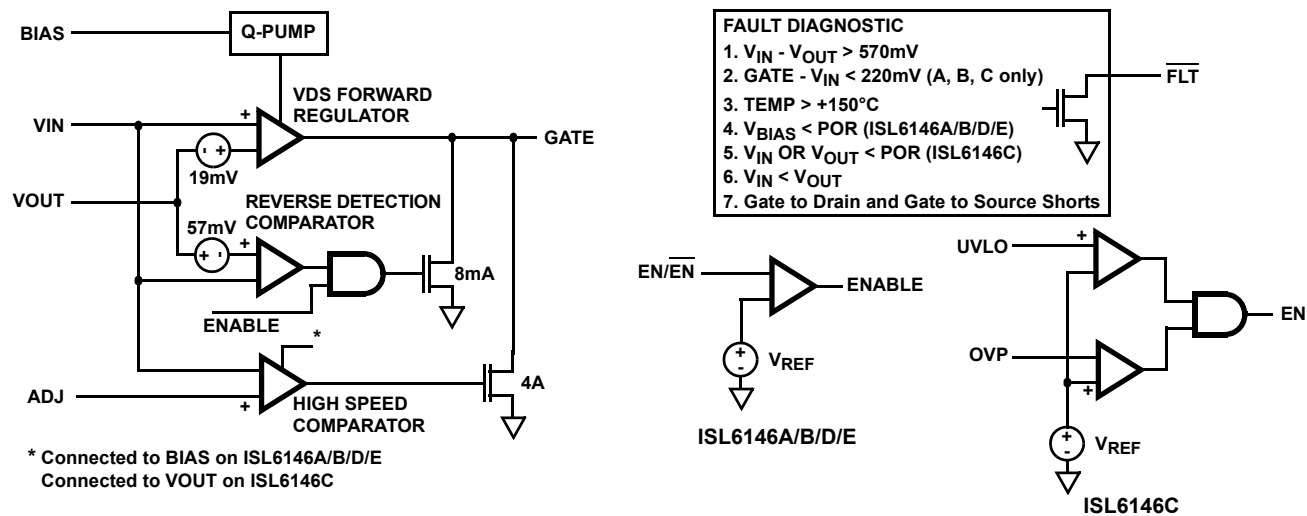
FIGURE 2. ISL6146 GATE HIGH CURRENT PULL-DOWN

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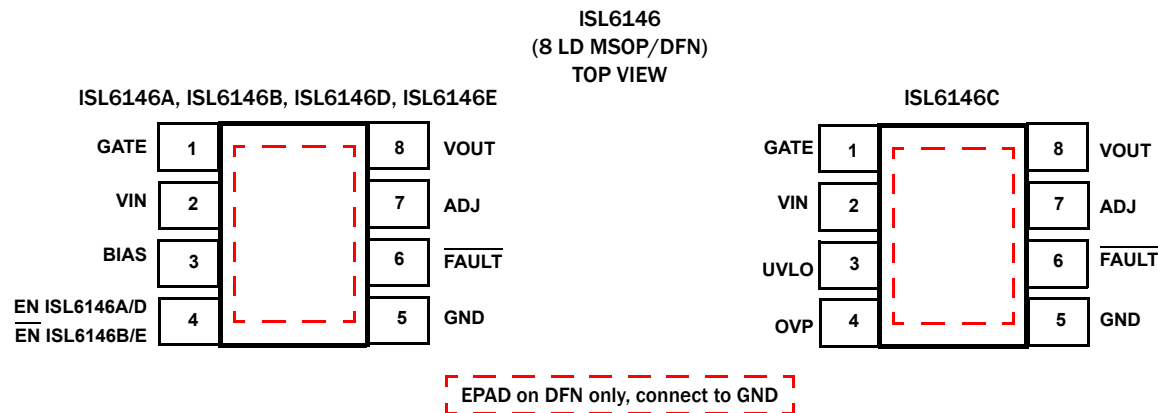
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Block Diagram



Pin Configuration



Pin Descriptions

| MSOP/DFN                                          | SYMBOL | DESCRIPTION                                                                                                                                                                                                                                                                                                                  |
|---------------------------------------------------|--------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1                                                 | GATE   | Gate Drive output to the external N-Channel MOSFET generated by the IC internal charge pump. Gate turn-on time is typically <1ms. Allows active control of external N-Channel FET gate to perform OR-ing function. The GATE drive is between $V_{IN} + 7V$ at $V_{IN} = 3.3V$ and $V_{IN} + 12V$ at $V_{IN} = 18V$ .         |
| 2                                                 | VIN    | Connected to the sourcing supply side (OR-ing MOSFET source), this pin serves as the sense pin to determine the OR'd supply voltage. The OR-ing MOSFET will be turned off when $V_{IN}$ becomes lower than $V_{OUT}$ by a value more than the externally set threshold or the defaulted internal threshold. Range: 0V to 24V |
| 3<br>ISL6146A<br>ISL6146B<br>ISL6146D<br>ISL6146E | BIAS   | Primary bias pin. Connected to an independent voltage supply greater than or equal to 3V and greater than $V_{IN}$ . Range: 3.0 to 24V                                                                                                                                                                                       |
| 3<br>ISL6146C                                     | UVLO   | Programmable UVLO protection to prevent premature turn-on prior to $V_{IN}$ being adequately biased. Range: 0V to 24V                                                                                                                                                                                                        |
| 4<br>ISL6146A<br>ISL6146D                         | EN     | Active high enable input to turn on the FET. Internally pulled low to GND through 2MΩ. Range: 0V to 24V                                                                                                                                                                                                                      |

## Pin Descriptions (Continued)

| MSOP/<br>DFN              | SYMBOL                    | DESCRIPTION                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
|---------------------------|---------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 4<br>ISL6146B<br>ISL6146E | $\overline{\text{EN}}$    | Active low enable input to turn on the FET. Internally pulled high to BIAS through 2M $\Omega$ . Range: 0 to 24V                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| 4<br>ISL6146C             | OVP                       | Programmable OV protection to prevent continued operation when the monitored voltage is too high. A back-to-back FET configuration must be employed to implement the OVP capability. Range: 0V to 24V                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
| 5                         | GND                       | Chip ground reference.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| 6                         | $\overline{\text{FAULT}}$ | Open-drain pull-down fault indicating output with internal on-chip filtering ( $T_{\text{FLT}}$ ). The ISL6146 fault detection circuitry pulls down this pin to GND as it detects a fault or a disabled input ( $\text{EN} = '0'$ or $\overline{\text{EN}} = '1'$ ).<br>Different types of faults and their detection mechanisms are discussed in more detail on <a href="#">page 17</a> . These faults include:<br>a. GATE is OFF ( $\text{GATE} < V_{\text{IN}} + 0.2\text{V}$ ) when enabled [this condition is not reported on the ISL6146D and ISL6146E]<br>b. $V_{\text{IN}} - V_{\text{OUT}} > 0.57\text{V}$ when ON.<br>c. FET G-D or G-S or D-S shorts.<br>d. $V_{\text{IN}} < \text{POR}_{\text{L2H}}$<br>e. $V_{\text{IN}} < V_{\text{OUT}}$<br>f. Over-Temperature<br>Range: 0 to $V_{\text{OUT}}$ |
| 7                         | ADJ                       | Resistor programmable $V_{\text{IN}} - V_{\text{OUT}}$ Voltage Threshold ( $V_{\text{th}}$ ) of the High Speed Comparator. This pin is either directly connected to VOUT or can be connected through a 5k $\Omega$ to 100k $\Omega$ resistor to GND. Allows for adjusting the voltage difference threshold to prevent unintended turn-off of the pass FET due to normal system voltage fluctuations.<br>Range: 0.4 to $V_{\text{OUT}}$                                                                                                                                                                                                                                                                                                                                                                         |
| 8                         | VOUT                      | The second sensing node for external FET control and connected to the Load side (OR-ing MOSFET Drain). This is the common connection point for multiple paralleled supplies. $V_{\text{OUT}}$ is compared to $V_{\text{IN}}$ to determine when the OR-ing FET has to be turned off. Range: 0V to 24V                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| PAD                       | Thermal Pad               | Connect to GND                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |

## Ordering Information

| PART NUMBER<br>(Notes 1, 2, 3) | PART<br>MARKING                                                                               | TEMP RANGE<br>(°C) | PACKAGE<br>(Pb-free) | PKG.<br>DWG. # |
|--------------------------------|-----------------------------------------------------------------------------------------------|--------------------|----------------------|----------------|
| ISL6146AFUZ                    | 6146A                                                                                         | -40 to +125        | 8 Ld MSOP            | M8.118         |
| ISL6146AFRZ                    | 46AF                                                                                          | -40 to +125        | 8 Ld 3x3 DFN         | L8.3x3J        |
| ISL6146BFUZ                    | 6146B                                                                                         | -40 to +125        | 8 Ld MSOP            | M8.118         |
| ISL6146BFRZ                    | 46BF                                                                                          | -40 to +125        | 8 Ld 3x3 DFN         | L8.3x3J        |
| ISL6146CFUZ                    | 6146C                                                                                         | -40 to +125        | 8 Ld MSOP            | M8.118         |
| ISL6146CFRZ                    | 46CF                                                                                          | -40 to +125        | 8 Ld 3x3 DFN         | L8.3x3J        |
| ISL6146DFUZ                    | 6146D                                                                                         | -40 to +125        | 8 Ld MSOP            | M8.118         |
| ISL6146DFRZ                    | 46DF                                                                                          | -40 to +125        | 8 Ld 3x3 DFN         | L8.3x3J        |
| ISL6146EFUZ                    | 6146E                                                                                         | -40 to +125        | 8 Ld MSOP            | M8.118         |
| ISL6146EFRZ                    | 46EF                                                                                          | -40 to +125        | 8 Ld 3x3 DFN         | L8.3x3J        |
| ISL6146AEVAL1Z                 | ISL6146A Evaluation Board (If desired with ISL6146D, please contact support)                  |                    |                      |                |
| ISL6146BEVAL1Z                 | ISL6146B Evaluation Board (If desired with ISL6146E, please contact support)                  |                    |                      |                |
| ISL6146CEVAL1Z                 | ISL6146C Evaluation Board                                                                     |                    |                      |                |
| ISL6146DEVAL1Z                 | 1 pair of ISL6146D Mini Development Boards (If desired with ISL6146A, please contact support) |                    |                      |                |
| ISL6146EEVAL1Z                 | 1 pair of ISL6146E Mini Development Boards (If desired with ISL6146B, please contact support) |                    |                      |                |

### NOTES:

1. Add "-T\*" suffix for tape and reel. Please refer to [TB347](#) for details on reel specifications.
2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
3. For Moisture Sensitivity Level (MSL), please see device information page for [ISL6146](#). For more information on MSL please see techbrief [TB363](#).

## Absolute Maximum Ratings

|                                                  |                           |
|--------------------------------------------------|---------------------------|
| BIAS, VIN, VOUT                                  | -0.3V to +24V             |
| GATE                                             | -0.3V to 40V              |
| EN, EN, UVLO, OVP                                | -0.3V to +24V             |
| ADJ                                              | -0.3V to V <sub>OUT</sub> |
| FAULT                                            | -0.3V to V <sub>OUT</sub> |
| ESD Rating                                       |                           |
| Human Body Model (Tested per JESD22-A114E)       | 2.5kV                     |
| Machine Model (Tested per JESD22-A115-A)         | 250V                      |
| Latch-up (Tested per JESD-78B; Class 2, Level A) | 100mA                     |

## Thermal Information

|                                                |                           |                      |
|------------------------------------------------|---------------------------|----------------------|
| Thermal Resistance (Typical)                   | $\theta_{JA}$ (°C/W)      | $\theta_{JC}$ (°C/W) |
| MSOP Package (Notes 4, 7)                      | 140                       | 41                   |
| DFN Package (Notes 5, 6)                       | 46                        | 5                    |
| Maximum Junction Temperature (Plastic Package) | +150°C                    |                      |
| Storage Temperature Range                      | -65°C to +150°C           |                      |
| Pb-free Reflow Profile                         | see <a href="#">TB493</a> |                      |

## Recommended Operating Conditions

|                                     |                 |
|-------------------------------------|-----------------|
| Bias Supply Voltage Range           | +3V to +20V     |
| OR'd Supply Voltage Range           | +1V to BIAS     |
| Temperature Range (T <sub>A</sub> ) | -40°C to +125°C |

**CAUTION:** Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

### NOTES:

- $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief [TB379](#) for details.
- $\theta_{JA}$  is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief [TB379](#).
- For  $\theta_{JC}$ , the "case temp" location is the center of the exposed metal pad on the package underside.
- For  $\theta_{JC}$ , the "case temp" location is taken at the package top center

**Electrical Specifications** V<sub>CC</sub> = BIAS = 12V, unless otherwise stated. T<sub>A</sub> = +25°C to +85°C. **Boldface limits apply across the operating temperature range, -40°C to +125°C.**

| SYMBOL                | PARAMETERS                              | TEST CONDITIONS                                                                                     | MIN<br>(Note 8)            | TYP                   | MAX<br>(Note 8)               | UNITS |
|-----------------------|-----------------------------------------|-----------------------------------------------------------------------------------------------------|----------------------------|-----------------------|-------------------------------|-------|
| <b>BIAS</b>           |                                         |                                                                                                     |                            |                       |                               |       |
| POR <sub>L2H</sub>    | POR Rising                              | BIAS Rising, GATE Rising                                                                            | <b>1.9</b>                 | 2.5                   | <b>2.95</b>                   | V     |
| POR <sub>HYS</sub>    | POR Hysteresis                          |                                                                                                     |                            | 189                   |                               | mV    |
| IBIAS_en_18           | ISL6146A/B/D/E BIAS Current             | BIAS, V <sub>IN</sub> = 18V, ADJ, V <sub>OUT</sub> = 16.98V, enabled                                |                            | 3.6                   | 5                             | mA    |
| IVIN_en_18            | ISL6146A/B/D/E V <sub>IN</sub> Current  | BIAS, V <sub>IN</sub> = 18V, ADJ, V <sub>OUT</sub> = 16.98V, enabled                                |                            | 25                    | 40                            | μA    |
| IVIN_en_18            | ISL6146C V <sub>IN</sub> Current        | V <sub>IN</sub> = 18V, ADJ, V <sub>OUT</sub> = 16.98V, enabled                                      |                            | 3                     | 4.5                           | mA    |
| IVOUT_en_18           | ISL6146A/B/D/E V <sub>OUT</sub> Current | BIAS, V <sub>IN</sub> = 18V, V <sub>OUT</sub> = 16.98V, enabled                                     |                            | 14                    | 20                            | μA    |
| VOUT_en_18            | ISL6146C V <sub>OUT</sub> Current       | V <sub>IN</sub> = 18V, V <sub>OUT</sub> = 16.98V, enabled                                           |                            | 400                   | 500                           | μA    |
| IBIAS_den_18          | ISL6146A/B/D/E BIAS Current             | BIAS, V <sub>IN</sub> = 18V, ADJ, V <sub>OUT</sub> = 16.98V, disabled                               |                            | 1.7                   | 3                             | mA    |
| IVIN_den_18           | ISL6146A/B/D/E V <sub>IN</sub> Current  | BIAS, V <sub>IN</sub> = 18V, ADJ, V <sub>OUT</sub> = 16.98V, disabled                               |                            | 27                    | 37                            | μA    |
| IVIN_den_18           | ISL6146C V <sub>IN</sub> Current        | V <sub>IN</sub> = 18V, ADJ, V <sub>OUT</sub> = 16.98V, disabled                                     |                            | 1.3                   | 1.5                           | mA    |
| IVOUT_den_18          | ISL6146A/B/D/E V <sub>OUT</sub> Current | BIAS, V <sub>IN</sub> = 18V, V <sub>OUT</sub> = 16.98V, disabled                                    |                            | 14                    | 20                            | μA    |
| IVOUT_den_18          | ISL6146C V <sub>OUT</sub> Current       | V <sub>IN</sub> = 18V, V <sub>OUT</sub> = 16.98V, disabled                                          |                            | 385                   | 500                           | μA    |
| t <sub>BIAS2GTE</sub> | BIAS to GATE Delay                      | BIAS > POR <sub>L2H</sub> to GATE Rising                                                            |                            | 150                   | 210                           | μs    |
| <b>GATE</b>           |                                         |                                                                                                     |                            |                       |                               |       |
| V <sub>GH_3</sub>     | Charge Pump Voltage                     | V <sub>IN</sub> , BIAS = 3V V <sub>IN</sub> - V <sub>OUT</sub> > V <sub>FWD_VR</sub>                | <b>V<sub>IN</sub> + 5V</b> | V <sub>IN</sub> + 7V  | <b>V<sub>IN</sub> + 10.5V</b> | V     |
| V <sub>GH_12</sub>    | Charge Pump Voltage                     | V <sub>IN</sub> , BIAS = 12V V <sub>IN</sub> - V <sub>OUT</sub> > V <sub>FWD_VR</sub>               | <b>V<sub>IN</sub> + 9V</b> | V <sub>IN</sub> + 10V | <b>V<sub>IN</sub> + 17.5V</b> | V     |
| V <sub>GH_18</sub>    | Charge Pump Voltage                     | V <sub>IN</sub> , BIAS = 18V V <sub>IN</sub> - V <sub>OUT</sub> > V <sub>FWD_VR</sub>               | <b>V<sub>IN</sub> + 9V</b> | V <sub>IN</sub> + 10V | <b>V<sub>IN</sub> + 18V</b>   | V     |
| V <sub>GL</sub>       | Low Voltage Level                       | V <sub>IN</sub> - V <sub>OUT</sub> < 0V                                                             |                            | 0                     | <b>0.1</b>                    | V     |
| I <sub>PDL</sub>      | Low Pull-Down Current                   | V <sub>IN</sub> = 12V, V <sub>OUT</sub> = 12.2V ADJ = 11V                                           | <b>5</b>                   | 8.4                   | <b>13</b>                     | mA    |
| I <sub>PDH</sub>      | High Pull-Down Current                  | V <sub>IN</sub> falling from 12V to 10V in 2μs                                                      | <b>3.5</b>                 | 6.5                   |                               | A     |
| t <sub>toff</sub>     | Fast Turn-off Time                      | V <sub>IN</sub> = V <sub>BIAS</sub> = 12V, V <sub>GATE</sub> = 18V to 10V, C <sub>GATE</sub> = 57nF |                            | 65                    | <b>130</b>                    | ns    |

**Electrical Specifications**  $V_{CC} = \text{BIAS} = 12\text{V}$ , unless otherwise stated.  $T_A = +25^\circ\text{C}$  to  $+85^\circ\text{C}$ . **Boldface limits apply across the operating temperature range,  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ . (Continued)**

| SYMBOL                            | PARAMETERS                                                              | TEST CONDITIONS                                                                                                                                                                                     | MIN<br>(Note 8) | TYP  | MAX<br>(Note 8) | UNITS         |
|-----------------------------------|-------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|------|-----------------|---------------|
| $t_{\text{offs}}$                 | Slow Turn-off Time                                                      | $V_{\text{IN}} = V_{\text{BIAS}} = 12\text{V}$ , $V_{\text{GATE}} = 18\text{V}$ to $10\text{V}$ ,<br>$C_{\text{GATE}} = 57\text{nF}$                                                                |                 | 58   | <b>80</b>       | $\mu\text{s}$ |
| $I_{\text{ON}}$                   | Turn-on Current                                                         | $\text{BIAS} = 12\text{V}$ , $V_{\text{G}} = 0\text{V}$                                                                                                                                             |                 | 1    |                 | mA            |
|                                   |                                                                         | $\text{BIAS} = 12\text{V}$ , $V_{\text{G}} = 20\text{V}$                                                                                                                                            |                 | 0.15 |                 | mA            |
| $V_{\text{VG\_FLT}}^{\text{r}}$   | GATE to $V_{\text{IN}}$ Rising Fault Voltage                            | $\text{GATE} > V_{\text{IN}}$ , enabled, $\overline{\text{FLT}}$ output is high.<br>(Does not apply to ISL6146D and ISL6146E)                                                                       | <b>320</b>      | 440  | <b>560</b>      | mV            |
| $V_{\text{VG\_FLT}}^{\text{f}}$   | GATE to $V_{\text{IN}}$ Falling Fault Voltage                           | $\text{GATE} > V_{\text{IN}}$ , enabled, $\overline{\text{FLT}}$ output is low.<br>(Does not apply to ISL6146D and ISL6146E)                                                                        | <b>140</b>      | 220  | <b>300</b>      | mV            |
| <b>CONTROL AND REGULATION I/O</b> |                                                                         |                                                                                                                                                                                                     |                 |      |                 |               |
| $V_{\text{Rr}}$                   | Reverse Voltage Detection<br>Rising $V_{\text{OUT}}$ Threshold          | $V_{\text{OUT}}$ rising                                                                                                                                                                             | <b>35</b>       | 57   | <b>79</b>       | mV            |
| $V_{\text{Rf}}$                   | Reverse Voltage Detection<br>Falling $V_{\text{OUT}}$ Threshold         | $V_{\text{OUT}}$ falling                                                                                                                                                                            | <b>10</b>       | 30   | <b>51</b>       | mV            |
| $t_{\text{Rs}}$                   | Reverse Voltage Detection Response<br>Time                              |                                                                                                                                                                                                     |                 | 10   |                 | $\mu\text{s}$ |
| $V_{\text{FWD\_VR}}$              | Amplifier Forward Voltage Regulation                                    | ISL6146 controls voltage across FET $V_{\text{DS}}$ to<br>$V_{\text{FWD\_VR}}$ during static forward operation at loads<br>resulting in $I_{\text{d}} \cdot r_{\text{DS(ON)}} < V_{\text{FWD\_VR}}$ | <b>11</b>       | 19   | <b>28</b>       | mV            |
| $V_{\text{OS\_HS}}$               | HS Comparator Input Offset Voltage                                      |                                                                                                                                                                                                     | <b>-14</b>      | 0.7  | <b>14</b>       | mV            |
| $V_{\text{TH(HS5k)}}$             | ADJ Adjust Threshold with 5k to GND                                     | $R_{\text{ADJ}} = 5\text{k}\Omega$ to GND                                                                                                                                                           | <b>0.57</b>     | 0.8  | <b>1.1</b>      | V             |
| $V_{\text{TH(HS100k)}}$           | ADJ Adjust Threshold with 100k to GND                                   | $R_{\text{ADJ}} = 100\text{k}\Omega$ to GND                                                                                                                                                         | <b>10</b>       | 40   | <b>95</b>       | mV            |
| $t_{\text{HSpd}}$                 | HS Comparator Response Time                                             | $V_{\text{OUT}} > V_{\text{IN}}$ , 1ns transition, 5V differential                                                                                                                                  |                 | 170  |                 | ns            |
| $V_{\text{FWD\_FLT}}$             | $V_{\text{IN}}$ to $V_{\text{OUT}}$ Forward Fault Voltage               | $V_{\text{IN}} > V_{\text{OUT}}$ , GATE is fully on, $\overline{\text{FLT}}$ output is low                                                                                                          | 330             | 450  | 570             | mV            |
| $V_{\text{FWD\_FLT\_HYS}}$        | $V_{\text{IN}}$ to $V_{\text{OUT}}$ Forward Fault Voltage<br>Hysteresis | $V_{\text{IN}} > V_{\text{OUT}}$ , GATE is fully on, $\overline{\text{FLT}}$ output is high                                                                                                         |                 | 44   |                 | mV            |
| <b>FAULT OUTPUT</b>               |                                                                         |                                                                                                                                                                                                     |                 |      |                 |               |
| $I_{\text{FLT\_SINK}}$            | $\overline{\text{FAULT}}$ Sink Current                                  | $\text{BIAS} = 18\text{V}$ $\overline{\text{FAULT}} = 0.5\text{V}$ , $V_{\text{IN}} < V_{\text{OUT}}$ , $V_{\text{GATE}} = V_{\text{GL}}$                                                           | <b>5</b>        | 9    |                 | mA            |
| $I_{\text{FLT\_LEAK}}$            | $\overline{\text{FAULT}}$ Leakage Current                               | $\overline{\text{FAULT}} = "V_{\text{FLT\_H}}"$ , $V_{\text{IN}} > V_{\text{OUT}}$ , $V_{\text{GATE}} = V_{\text{IN}} + V_{\text{GQP}}$                                                             |                 | 0.04 | <b>10</b>       | $\mu\text{A}$ |
| $t_{\text{FLT\_L2H}}$             | $\overline{\text{FAULT}}$ Low to High Delay                             | $\text{GATE} = V_{\text{GQP}}$ to $\overline{\text{FAULT}}$ output is high                                                                                                                          |                 | 10   | <b>23</b>       | $\mu\text{s}$ |
| $t_{\text{FLT\_H2L}}$             | $\overline{\text{FAULT}}$ High to Low Delay                             | $\text{GATE} = V_{\text{IN}}$ to $\overline{\text{FAULT}}$ output is low                                                                                                                            |                 | 1.7  | <b>3</b>        | $\mu\text{s}$ |
| <b>ENABLE UVLO/OVP/ADJ INPUTS</b> |                                                                         |                                                                                                                                                                                                     |                 |      |                 |               |
| $V_{\text{thRa}}$                 | ISL6146A/D EN Rising $V_{\text{th}}$                                    |                                                                                                                                                                                                     | <b>580</b>      | 606  | <b>631</b>      | mV            |
| $V_{\text{thR\_hysa}}$            | ISL6146A/D EN $V_{\text{th}}$ Hysteresis                                |                                                                                                                                                                                                     |                 | -90  |                 | mV            |
| $V_{\text{thFb}}$                 | ISL6146B/E $\overline{\text{EN}}$ Falling $V_{\text{th}}$               |                                                                                                                                                                                                     | <b>580</b>      | 606  | <b>631</b>      | mV            |
| $V_{\text{thF\_hysb}}$            | ISL6146B/E $\overline{\text{EN}}$ $V_{\text{th}}$ Hysteresis            |                                                                                                                                                                                                     |                 | +90  |                 | mV            |
| $V_{\text{thFc}}$                 | ISL6146C OVP Falling $V_{\text{th}}$                                    |                                                                                                                                                                                                     | <b>580</b>      | 606  | <b>631</b>      | mV            |
| $V_{\text{thF\_hysc}}$            | ISL6146C OVP $V_{\text{th}}$ Hysteresis                                 |                                                                                                                                                                                                     |                 | +90  |                 | mV            |
| $V_{\text{thRc}}$                 | ISL6146C UVLO Rising $V_{\text{th}}$                                    |                                                                                                                                                                                                     | <b>580</b>      | 606  | <b>631</b>      | mV            |
| $V_{\text{thR\_hysc}}$            | ISL6146C UVLO $V_{\text{th}}$ Hysteresis                                |                                                                                                                                                                                                     |                 | -90  |                 | mV            |
| $t_{\text{EN2GTER}}$              | EN/UVLO Rising to GATE Rising Delay                                     |                                                                                                                                                                                                     |                 | 10   | <b>12</b>       | $\mu\text{s}$ |
|                                   | $\overline{\text{EN}}$ /OVP Falling to GATE Rising Delay                |                                                                                                                                                                                                     |                 | 9    | <b>12</b>       | $\mu\text{s}$ |

**Electrical Specifications**  $V_{CC} = \text{BIAS} = 12\text{V}$ , unless otherwise stated.  $T_A = +25^\circ\text{C}$  to  $+85^\circ\text{C}$ . **Boldface limits apply across the operating temperature range,  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ .** (Continued)

| SYMBOL               | PARAMETERS                            | TEST CONDITIONS                                   | MIN<br>(Note 8) | TYP  | MAX<br>(Note 8) | UNITS            |
|----------------------|---------------------------------------|---------------------------------------------------|-----------------|------|-----------------|------------------|
| $t_{\text{EN2GTEF}}$ | EN/UVLO Falling to GATE Falling Delay |                                                   |                 | 2    | <b>4</b>        | $\mu\text{s}$    |
|                      | EN/OVP Rising to GATE Falling Delay   |                                                   |                 | 2    | <b>4</b>        | $\mu\text{s}$    |
| Ren_h                | ENABLE Pull-down Resistor             | ISL6146A, ISL6146D                                |                 | 2    |                 | $\text{M}\Omega$ |
| Ren_l                | ENABLE Pull-up Resistor               | ISL6146B, ISL6146E                                |                 | 2    |                 | $\text{M}\Omega$ |
| Vadj                 | ADJ Pin Voltage                       | $R_{\text{ADJ}}$ 5k $\Omega$ to 100k $\Omega$     |                 | 0.4  |                 | V                |
| Radj                 | ADJ Pull-up Resistor                  | Internal ADJ pull-up resistor to $V_{\text{OUT}}$ |                 | 3.85 |                 | $\text{M}\Omega$ |
| OTS                  | Over-temperature Sense                | Fault signals in operation                        |                 | 140  |                 | $^\circ\text{C}$ |
| OTSHYS               | Over-temperature Sense Hysteresis     |                                                   |                 | 20   |                 | $^\circ\text{C}$ |
| HTS                  | High Temperature Sense                | Fault signals upon enabling                       |                 | 125  |                 | $^\circ\text{C}$ |

## NOTE:

8. Compliance to datasheet limits is assured by one or more methods: production test, characterization and/or design.

## Typical Performance Curves

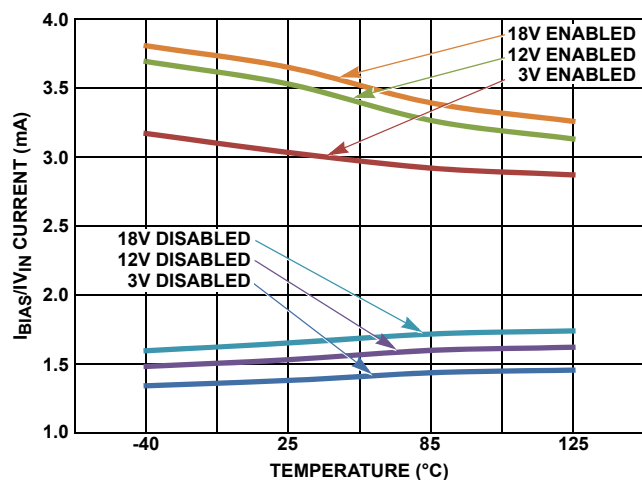


FIGURE 3. ISL6146A/B/D/E BIAS AND ISL6146C  $V_{IN}$  CURRENT vs TEMPERATURE

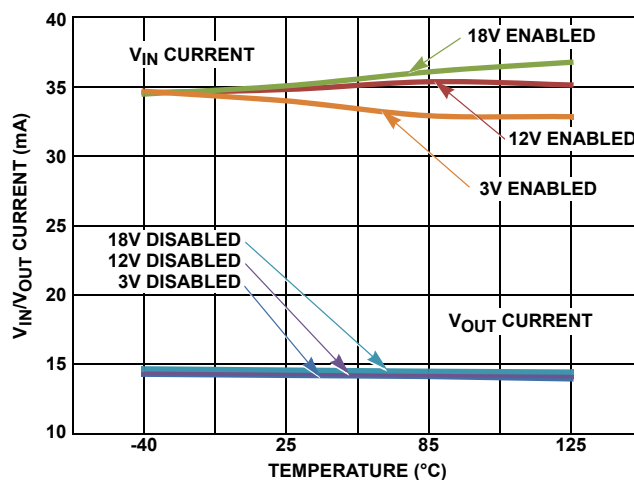


FIGURE 4. ISL6146A/B/C/D/E  $V_{IN}$  AND  $V_{OUT}$  CURRENT vs TEMPERATURE

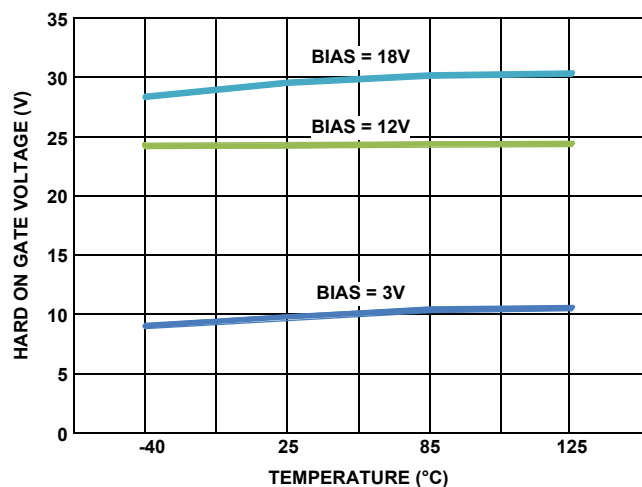


FIGURE 5. GATE VOLTAGE vs TEMPERATURE

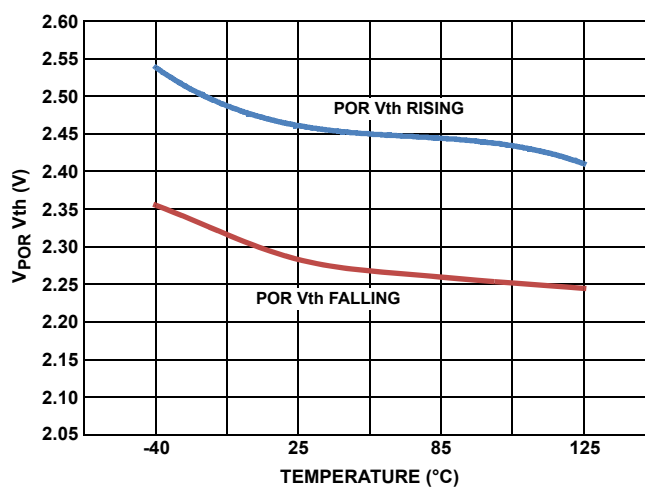


FIGURE 6. POR  $V_{th}$  RISING AND FALLING VOLTAGE

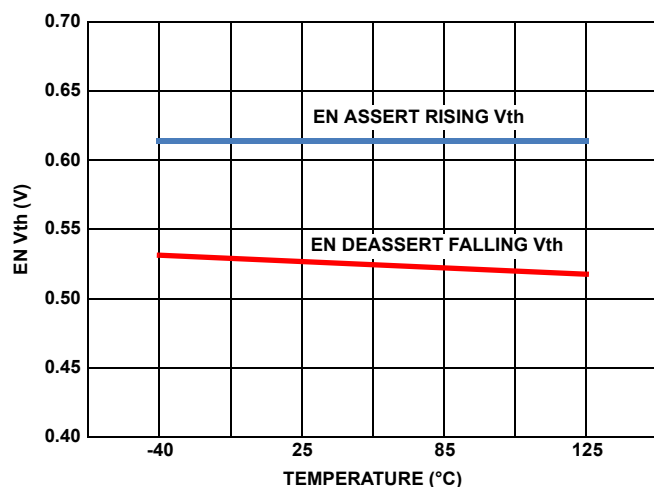


FIGURE 7. ISL6146A/D EN  $V_{th}$  vs TEMPERATURE

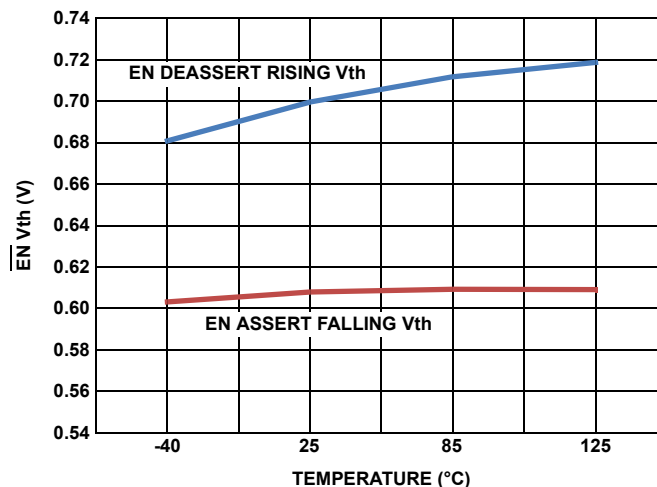


FIGURE 8. ISL6146B/E EN  $V_{th}$  vs TEMPERATURE

## Typical Performance Curves (Continued)

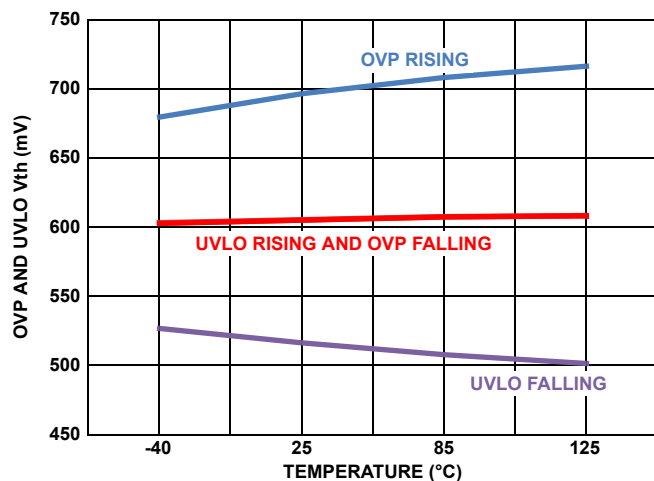


FIGURE 9. ISL6146C UVLO/OVP Vth vs TEMPERATURE

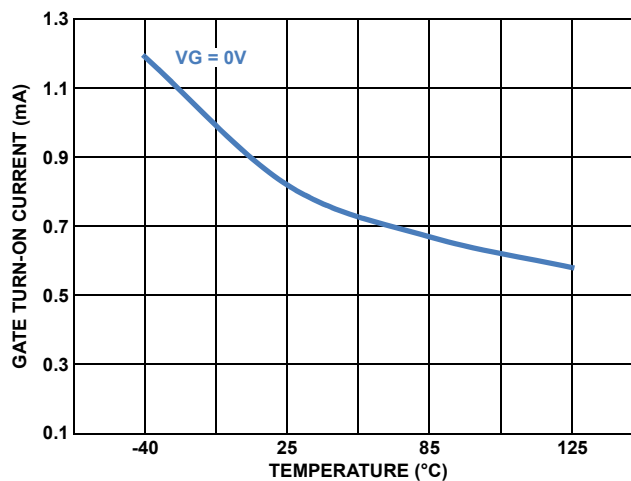
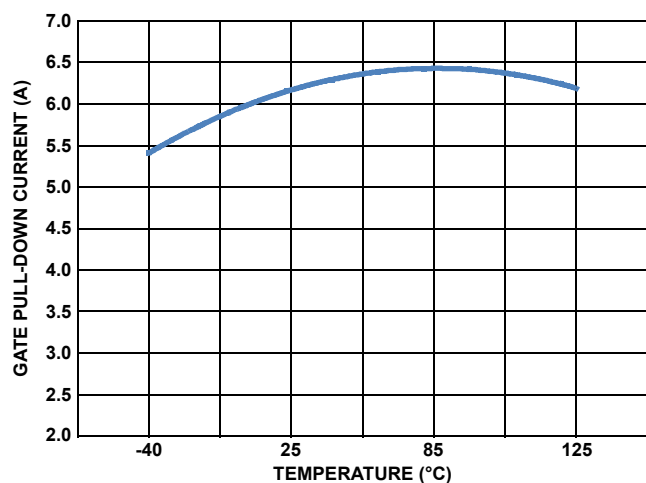
FIGURE 10. GATE TURN-ON CURRENT  $V_{IN} = 12V$ 

FIGURE 11. GATE HARD TURN-OFF CURRENT

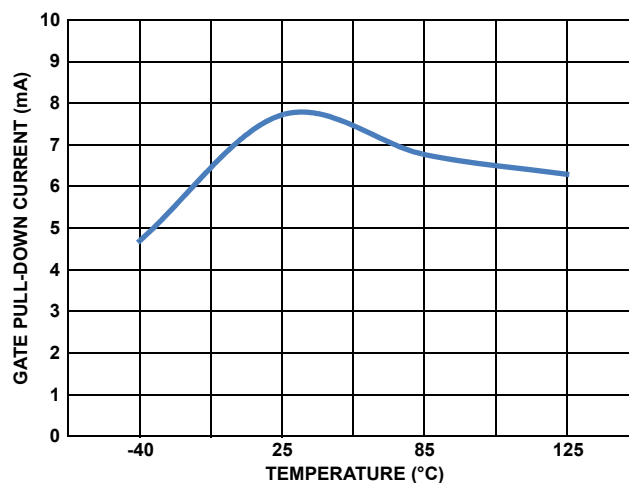


FIGURE 12. GATE SLOW TURN-OFF CURRENT

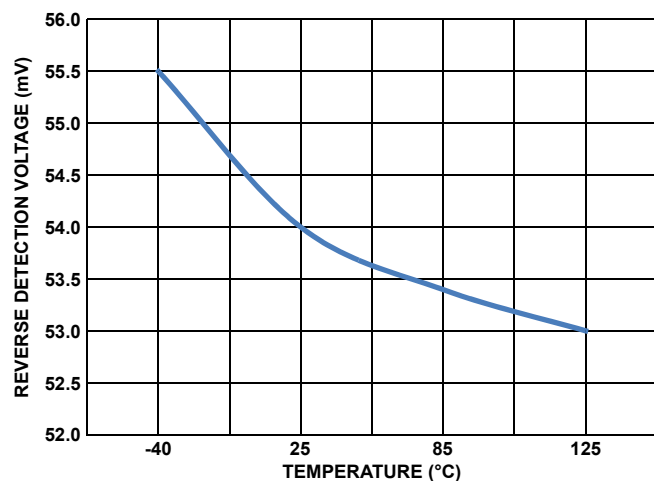


FIGURE 13. INCREASING REVERSE VOLTAGE DETECTION Vth

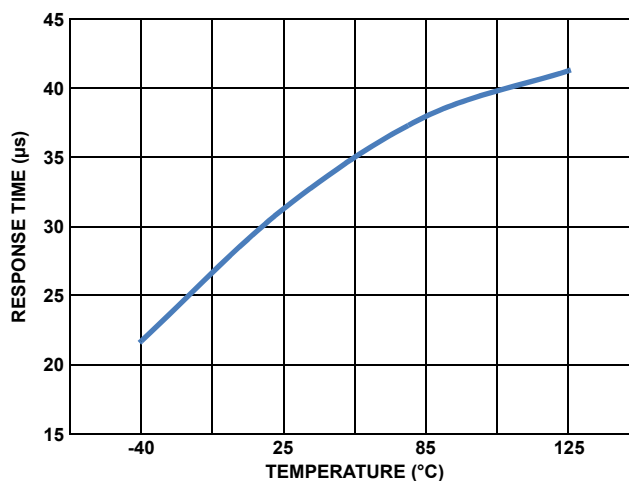


FIGURE 14. REVERSE VOLTAGE RESPONSE TIME

## Typical Performance Curves (Continued)

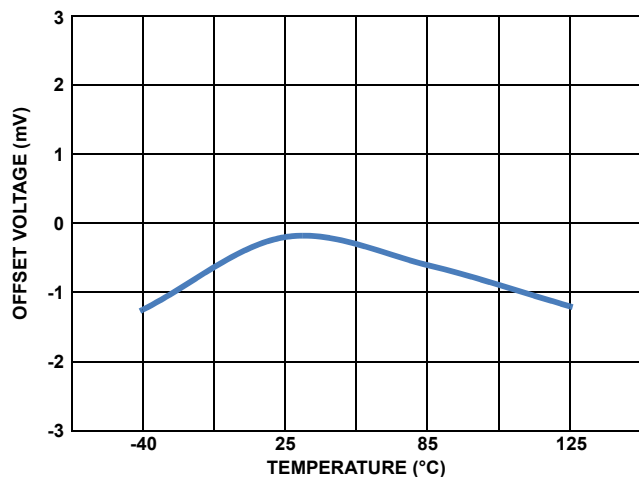


FIGURE 15. HIGH SPEED COMPARATOR OFFSET VOLTAGE

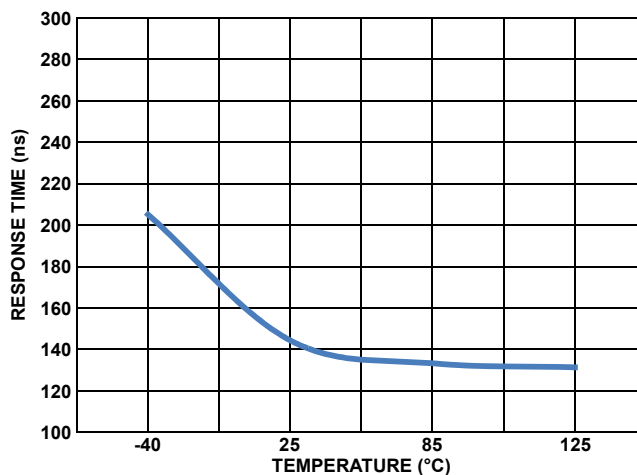


FIGURE 16. HIGH SPEED COMPARATOR RESPONSE TIME

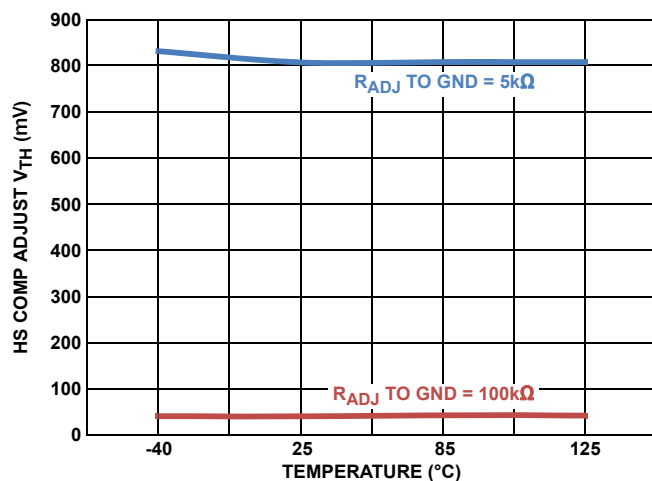


FIGURE 17. HS COMPARATOR ADJUSTABLE Vth

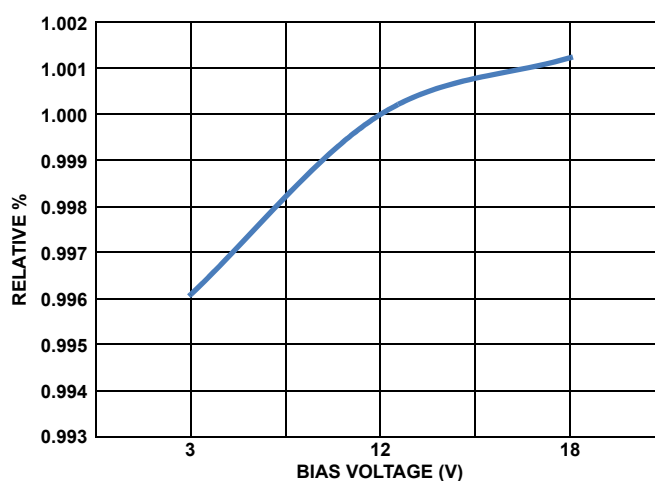
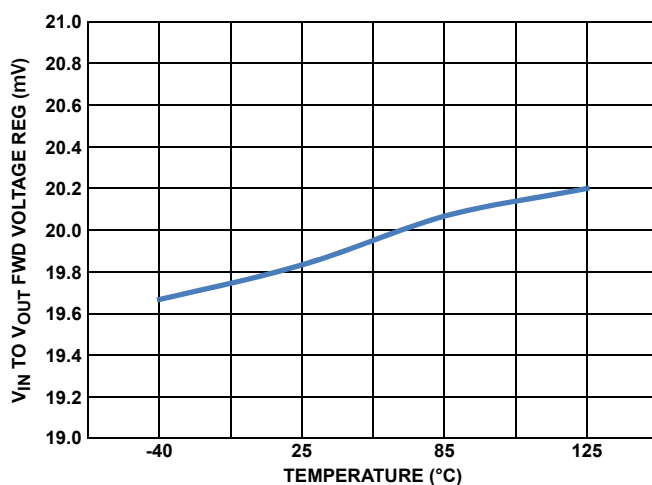
FIGURE 18. EN/ $\overline{\text{EN}}$ /OVP/UVLO Vth DELTA vs BIAS VOLTAGE  
NORMALIZED TO BIAS = 12V

FIGURE 19. FORWARD VOLTAGE REGULATION

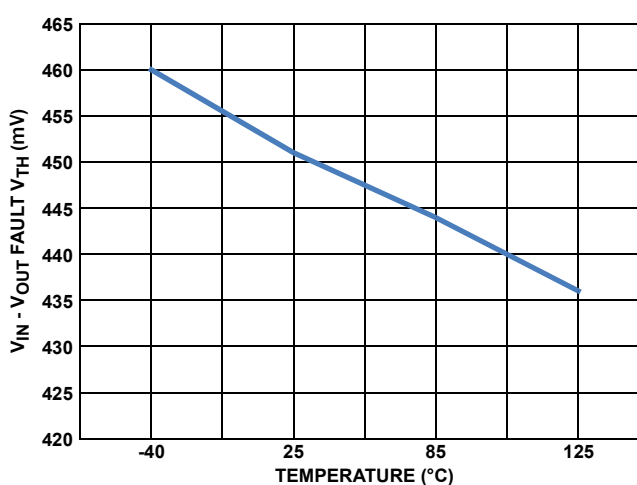


FIGURE 20. VIN TO VOUT FORWARD FAULT VOLTAGE

## Typical Performance Curves (Continued)

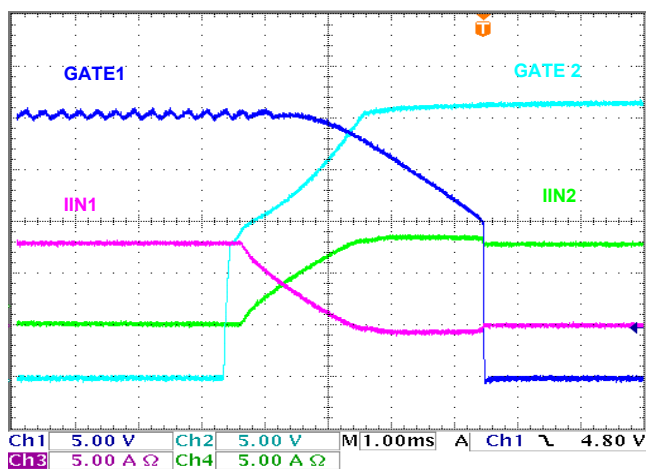


FIGURE 21. ISL6146C SLOW RAMP CONNECT 12V OR-ing

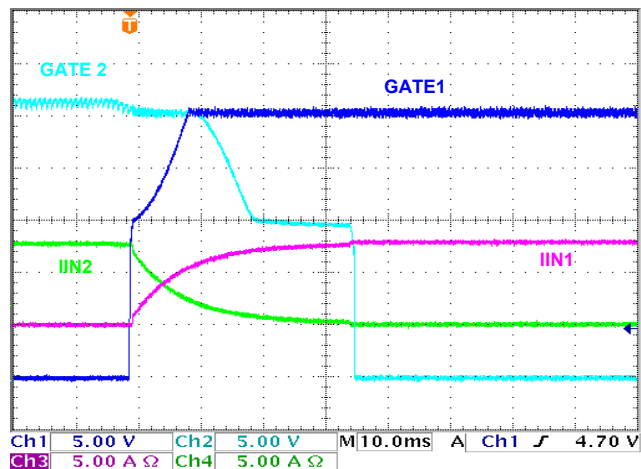


FIGURE 22. ISL6146C SLOW RAMP DISCONNECT 12V OR-ing

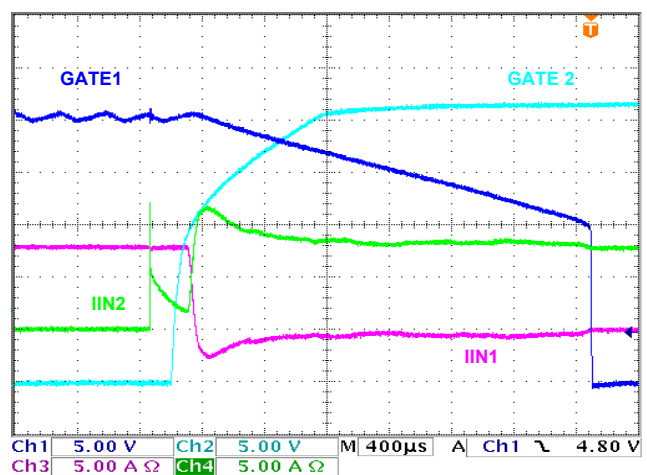


FIGURE 23. ISL6146C HOT SWAP CONNECT 12V OR-ing

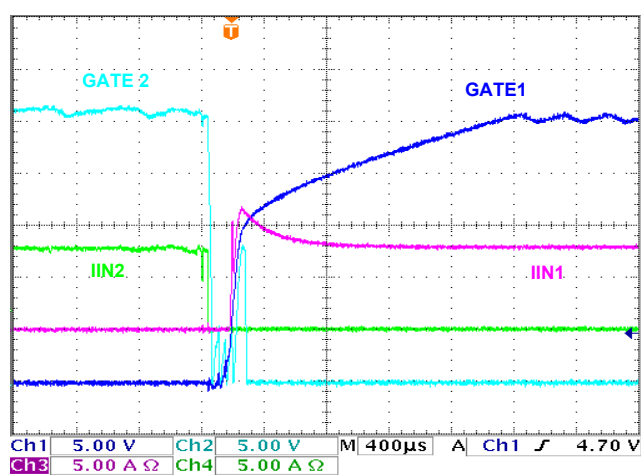


FIGURE 24. ISL6146C HOT DISCONNECT 12V OR-ing

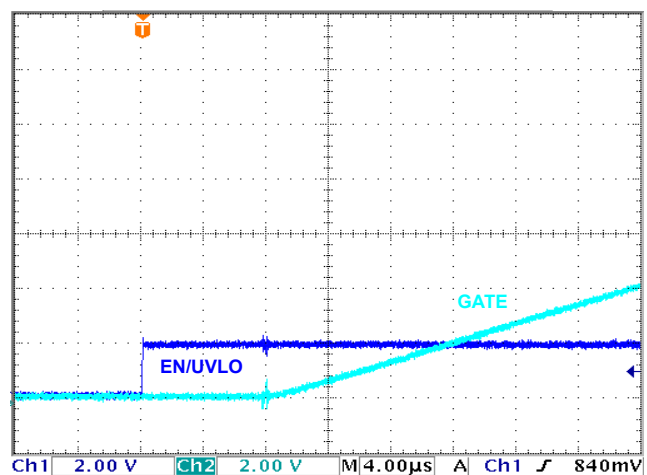


FIGURE 25. ISL6146A/D EN/ISL6146C UVLO TO GATE ON DELAY

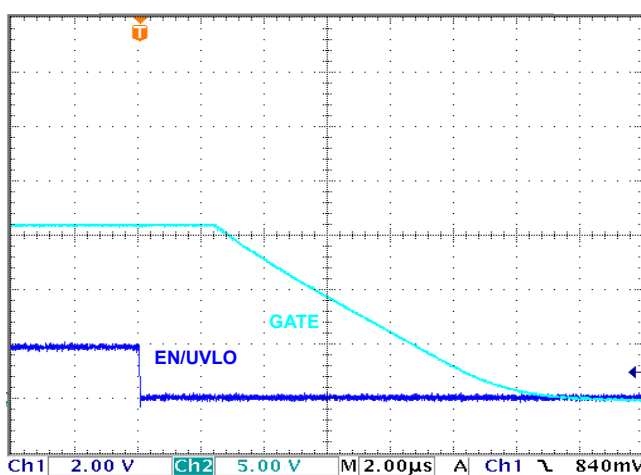


FIGURE 26. ISL6146A/D EN/ISL6146C UVLO TO GATE OFF DELAY

## Typical Performance Curves (Continued)

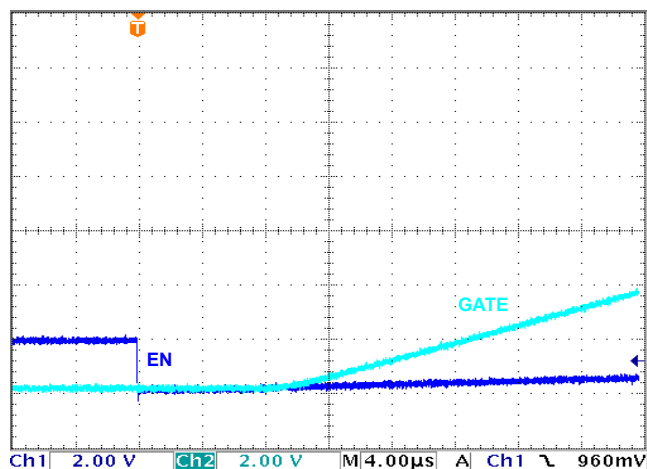
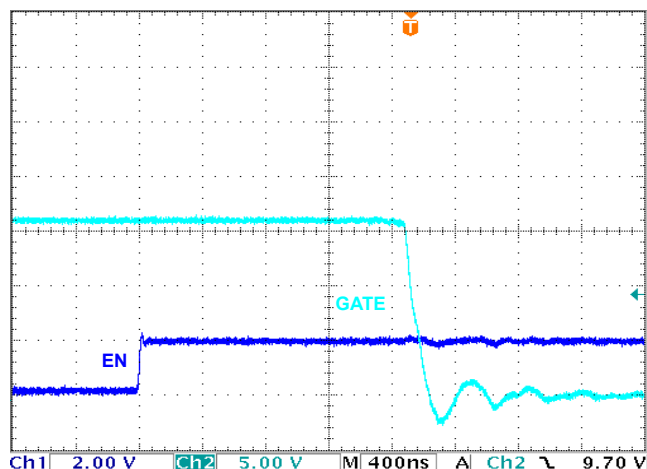
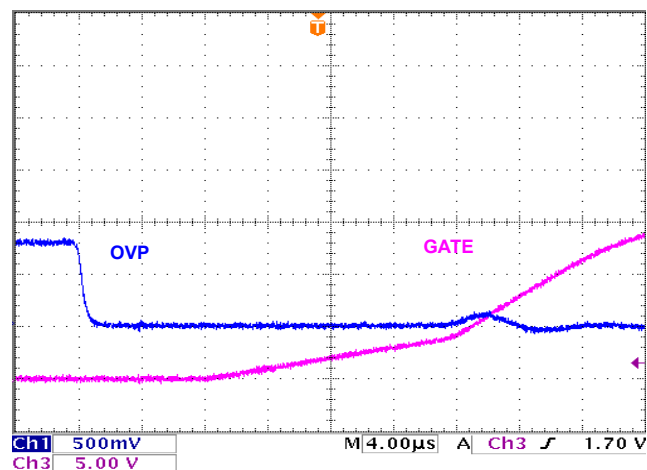
FIGURE 27. ISL6146B/E  $\overline{\text{EN}}$  TO GATE ON DELAYFIGURE 28. ISL6146B/E  $\overline{\text{EN}}$  TO GATE OFF DELAY

FIGURE 29. ISL6146C OVP TO GATE ON DELAY

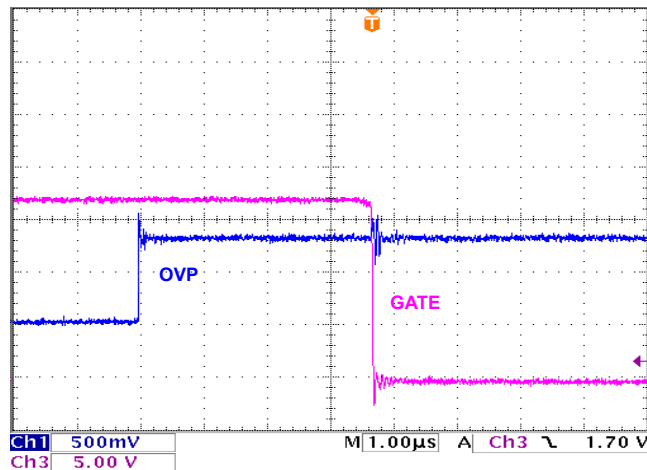
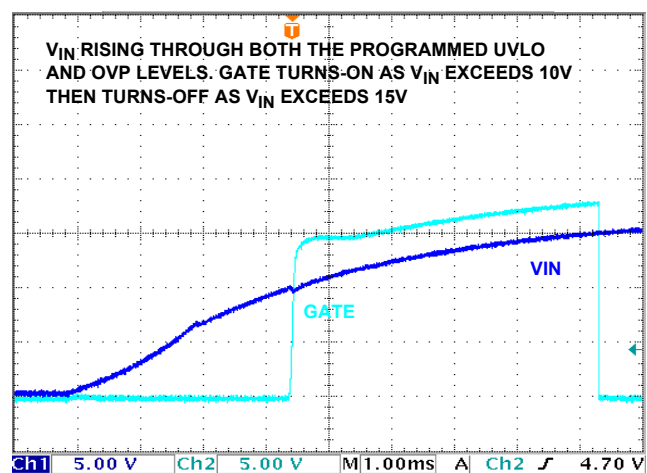
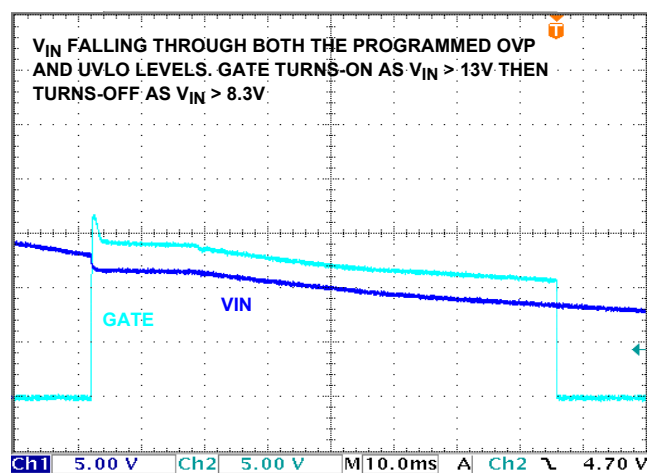


FIGURE 30. ISL6146C OVP TO GATE OFF DELAY

FIGURE 31. ISL6146C RISING  $V_{\text{IN}}$ , UVLO AND OVP FUNCTIONFIGURE 32. ISL6146C FALLING,  $V_{\text{IN}}$  OVP AND UVLO FUNCTION

## Typical Performance Curves (Continued)

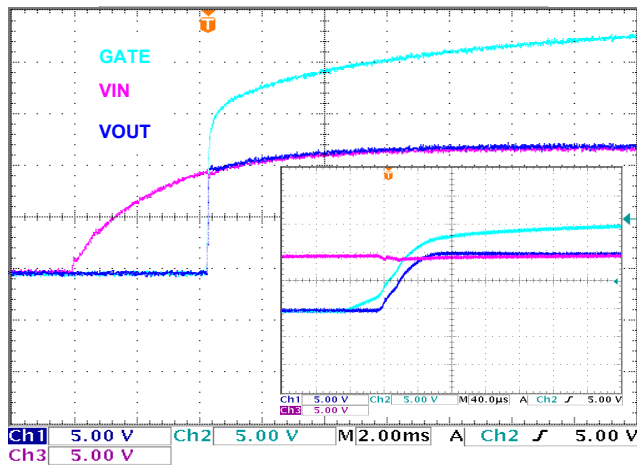


FIGURE 33. BACK-TO-BACK FET TURN\_ON DETAIL

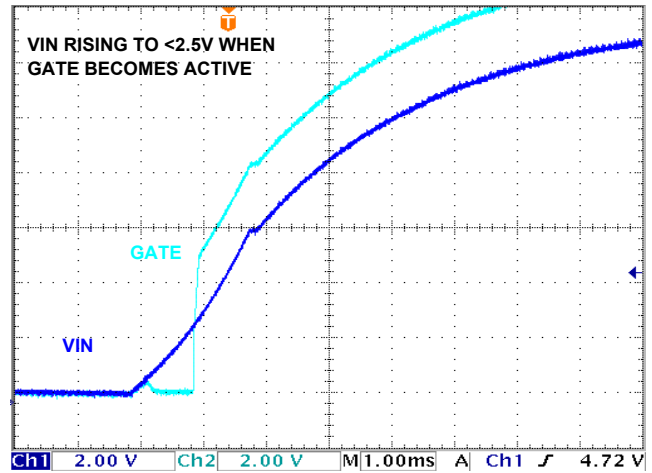
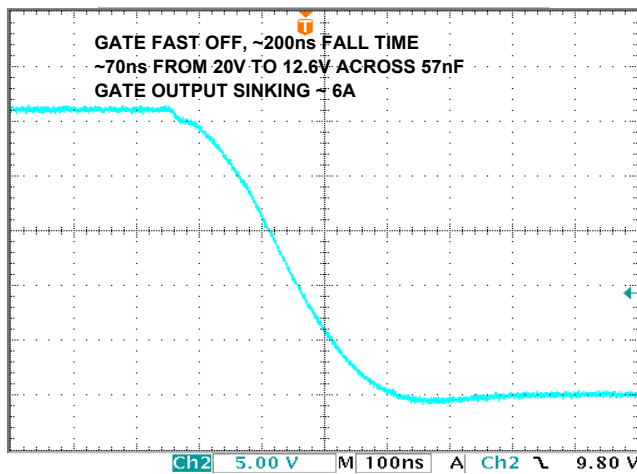
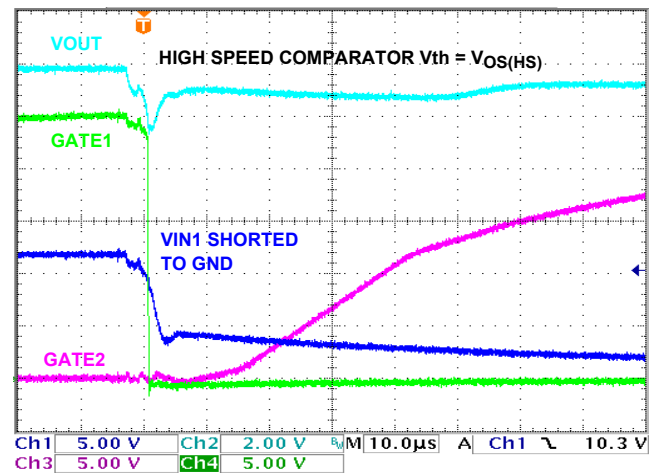
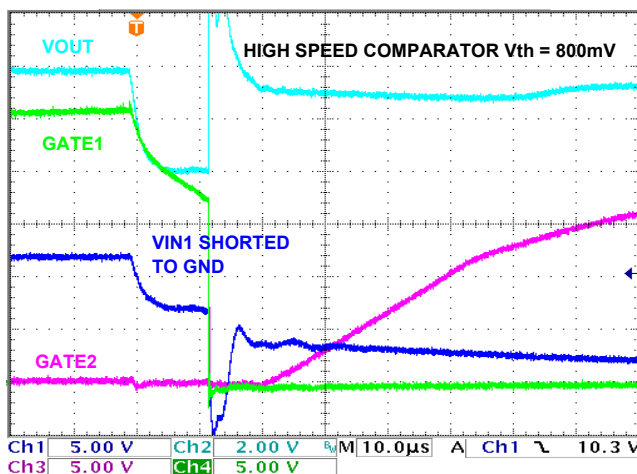
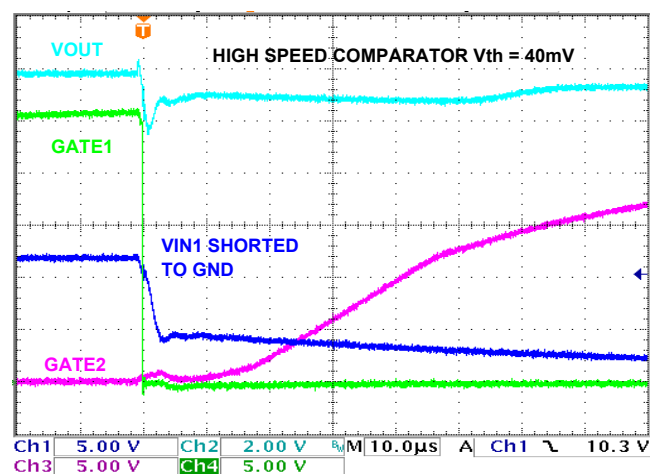
FIGURE 34. ISL6146 RISING POR  $V_{th}$ 

FIGURE 35. FAST GATE TURN-OFF WITH 57nF GATE

FIGURE 36. RESPONSE TO  $V_{IN}$  SHORTED TO GND WITH ADJ SHORTED TO  $V_{OUT}$ FIGURE 37. RESPONSE TO  $V_{IN}$  SHORTED TO GND WITH ADJ 5kΩ TO GNDFIGURE 38. RESPONSE TO  $V_{IN}$  SHORTED TO GND WITH ADJ 100kΩ TO GND

## Typical Performance Curves (Continued)

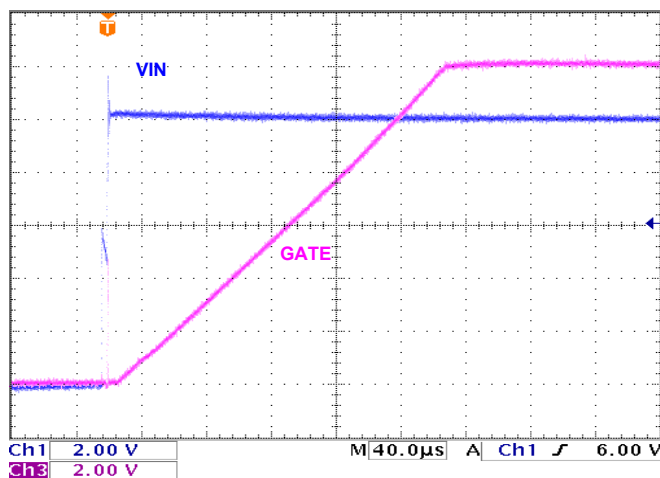
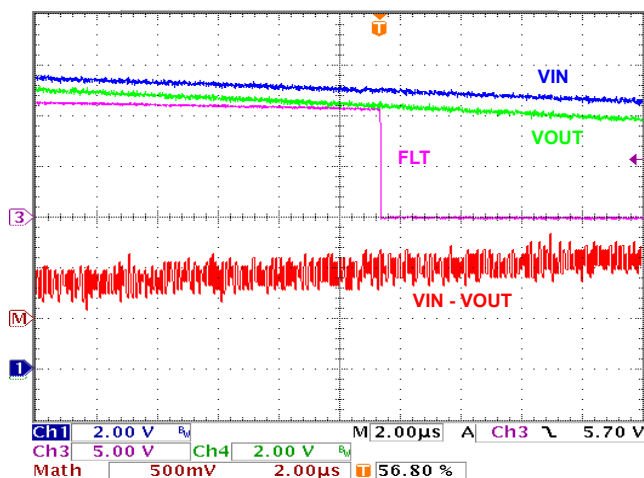
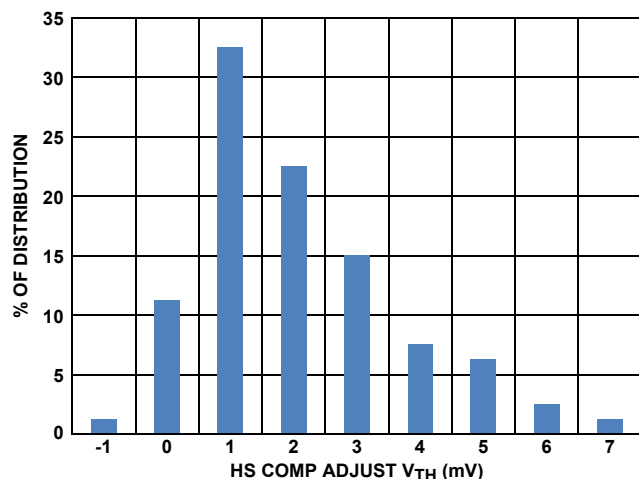
FIGURE 39.  $V_{IN}$  HOT SWAPPED TO GATE WITH BIAS = 12V NO LOADFIGURE 40. FAULT ASSERTING  $V_{IN}$  TO  $V_{OUT} > V_{FWD\_FLT}$ 

FIGURE 41. HIGH SPEED COMPARATOR OFFSET VOLTAGE DISTRIBUTION

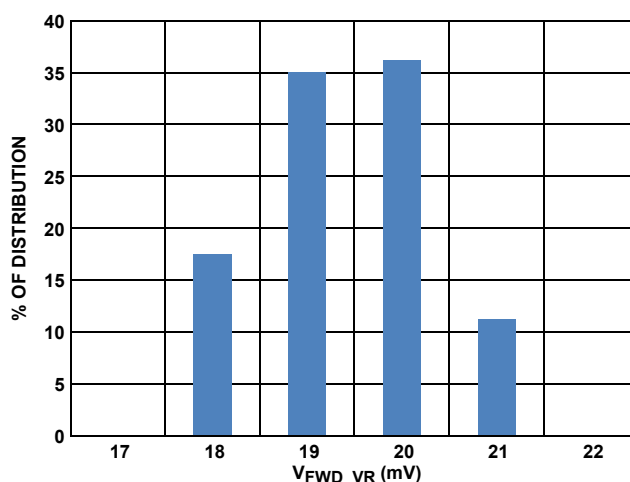


FIGURE 42. FORWARD REGULATION VOLTAGE DISTRIBUTION

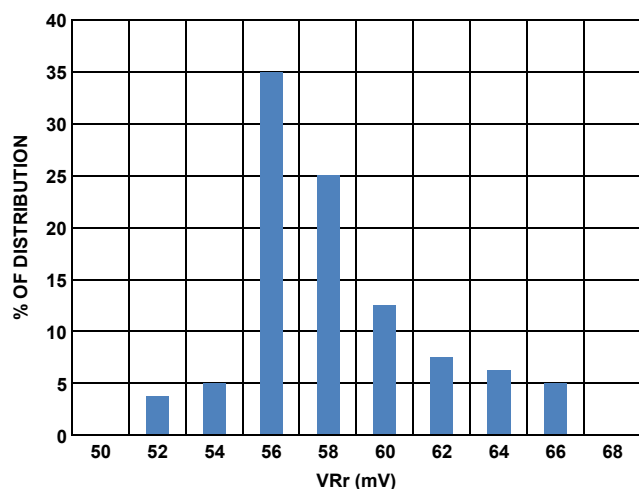


FIGURE 43. REVERSE DETECTION RISING VOLTAGE DISTRIBUTION

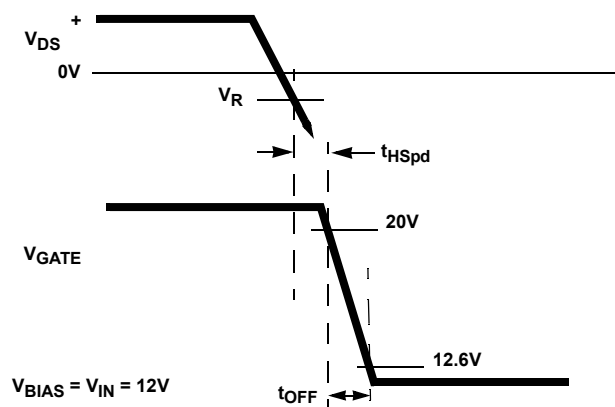


FIGURE 44. FAST RAMP REVERSE PROTECTION TIMING DIAGRAM

Typical Performance Curves (Continued)

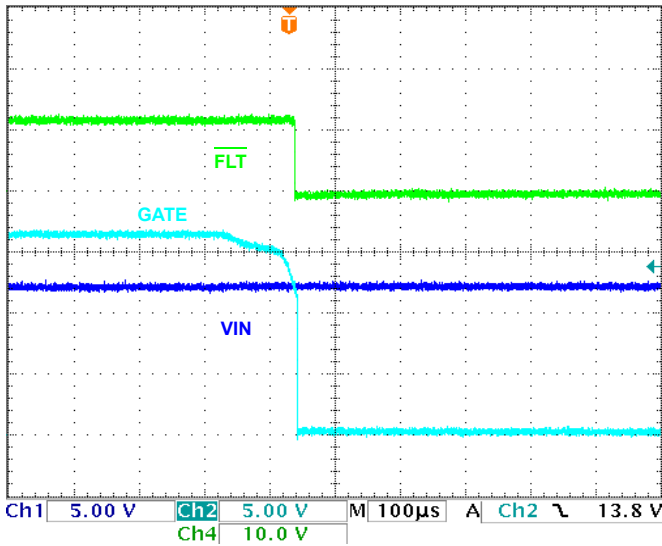


FIGURE 45. ISL6146A FLT RESPONSE TO NON-CONDUCTION

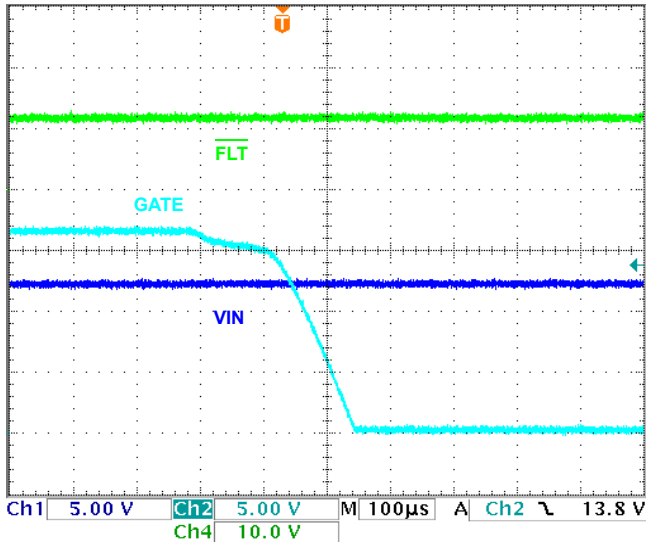


FIGURE 46. ISL6146D FLT RESPONSE TO NON-CONDUCTION

## Functional Description

### Functional Overview

In a redundant power distribution system, similar potential and parallel power supplies each contribute to the load current through various active and passive current sharing schemes. Typically, OR-ing power diodes are used to protect against reverse current flow in the event that one of the power supplies falls below the common bus voltage or develops a catastrophic failure. However, using a discrete OR-ing diode solution has some significant drawbacks. The primary downside is the increased power dissipation loss in the OR-ing diodes as system power requirements increase. At the lowest voltages where the ISL6146 is designed for use, the voltage distribution losses across an OR-ing diode can be a significant percentage, in some cases approaching 70%. Another disadvantage when using an OR-ing diode is failure to detect a shorted or opened current path, which jeopardizes system power availability and reliability. An open diode may reduce the system to a single point of failure while a shorted diode eliminates the system's power protection.

Using an active OR-ing FET controller, such as the ISL6146, helps with these potential issues. The use of a low on-resistance FET as the OR-ing component allows for a more efficient system design as the voltage across the FET is much lower than that across a forward biased diode. Additionally, the ISL6146 has a dedicated fault (FAULT) output pin that indicates when there is a conditional or FET fault short providing the diagnostic capability that a diode is unable to.

The ISL6146 is designed to OR together voltages as low as 1V when supplied with a separate bias supply of 3V or greater. Otherwise, the ISL6146 is designed to be biased from and OR voltages across the 3V to 20V nominal supply range.

In a single FET configuration as voltage is first applied to a VIN pin, the FET body diode conducts providing all the ISL6146s connected on a common bus circuit, bias via the VOUT pins. As individual power supply voltages ramp up in excess of the rising POR threshold, the ISL6146's internal charge pump activates to provide a floating gate drive voltage for the external N-channel OR-ing MOSFET, thus turning the FETs on once  $V_{IN} > V_{OUT}$ . The ISL6146 continuously monitors the drain and source of the OR-ing FET and provides a reverse voltage (N-channel MOSFET  $V_{OUT} - V_{IN}$ ) detection threshold (VR) that, when exceeded, indicates a reverse current condition. Once this threshold is exceeded, the ISL6146 turns off the OR-ing FET by pulling down the GATE pin to GND. The ISL6146 also provides high speed  $V_{OUT} > V_{IN}$  transient protection as in the case of a catastrophic VIN failure. The ISL6146 additionally provides for adjustment of the  $V_{IN} - V_{OUT}$  reverse voltage Vth (VR Vth) via the ADJ pin of the ISL6146 with an external resistor to GND. This allows adjusting the  $V_{IN} - V_{OUT}$  voltage threshold level to compensate for normal system voltage fluctuations, thus eliminating unnecessary reaction by the ISL6146.

The total  $V_{IN} - V_{OUT}$  VR Vth is the sum of both the internal offset and the external programmed VR Vth.

In the event of a  $V_{OUT} > V_{IN}$  condition, the ISL6146 responds either with a high or low current pull-down on the GATE pin depending on whether the High Speed comparator (HSCOMP) has been activated or not. The HSCOMP determines if the VR occurred within 1μs, by continuously monitoring the FET VDS and if so, the high pull-down current is used to turn off the OR-ing FET. In the event of a falling  $V_{IN}$  transition in <1μs, (i.e., a catastrophic failure of the power source) the HSCOMP protects the common bus from the individual faulted power supply short by turning off the shorted supply's OR-ing MOSFET in less than 300ns, ensuring the integrity of the common bus voltage from reverse current to the damaged supply.

Once the correct  $V_{IN} > V_{OUT}$  relationship is established again, the ISL6146 again turns on the FET.

The FAULT pin is an open drain, active low output indicating that a fault or specific condition has occurred, these include:

- GATE is OFF ( $GATE < V_{IN} + 0.2V$ ). Lack of conduction, not a fault, just not on. ISL6146D and ISL6146E do not respond to this condition
- Faults resulting in  $V_{IN} - V_{OUT} > 0.57V$  when ON
- An open FET resulting in body diode conduction
- Excessive current through FET
- FET Faults monitored and reported include
  - G-D, gate unable to drive to Q-pump voltage
  - G-S, gate unable to drive to Q-pump voltage
  - D-S shorts, when GATE is OFF  $V_{DS} < 2V$
  - $V_{IN} < POR$
  - Missing  $V_{IN}$
  - $V_{IN}$  shorted to GND

On the ISL6146C version, a conditional fault is also signalled if the  $V_{IN}$  is not within the programmed UVLO and OVP levels.

The ISL6146 has an on-chip over-temperature fault threshold of ~+140°C with a 20°C hysteresis. Although the ISL6146 itself produces little heat, it senses the environment in which it is, likely including a near by FET.

The ISL6146A/D and ISL6146B/E are functional variants with an enabling input of either polarity. This feature is used when the need to interrupt the current path via signaling is necessary. This is accomplished by implementing two FETs in series so that there is a body diode positioned to block current in either direction. This functionality is considered an additional enhancement to the OR-ing diode it replaces.

The ISL6146C employs the use of a programmable Undervoltage Lock Out (UVLO) and a programmable Overvoltage Protection (OVP) input. This allows the GATE to only turn-on when the monitored voltage is between the programmed lower and upper levels. This application would use the back-to-back FET configuration. In the event that the current path does not need to be interrupted then the EN, UVLO and OVP inputs can all be overridden.

The ISL6146D and ISL6146E are variants of the ISL6146A and ISL6146B respectively, the difference being the former do not respond to a nonconduction condition (when enabled and  $V_{IN} > V_{OUT}$ , the GATE is not on) unlike the latter that do signal a fault.

## Applications Information

### Power-up Considerations

#### BIAS AND $V_{IN}$ CONSTRAINTS

Upon power-up when the  $V_{IN}$  supply is separate from the BIAS supply, the BIAS voltage must be greater or equal to the  $V_{IN}$  voltage at all times.

When using a single supply for both the ISL6146 bias and the OR-ing supply, the  $V_{IN}$  and BIAS pins can be configured with a low value resistor between the two pins to provide some isolation and decoupling to support the chip bias even as the OR'd supply experiences voltage droops and surges. Although not necessary to do so, it is a best design practice for particularly noisy environments.

#### FET TO IC LAYOUT RECOMMENDATIONS

Connections from the FET(s) to the ISL6146  $V_{IN}$  and  $V_{OUT}$  pins must be Kelvin in nature and as close to the FET drain and source PCB pads as possible to eliminate any trace resistance errors that can occur with high currents. This connection placement is most critical to providing the most accurate voltage sensing particularly when the back-to-back FET configuration is used. Likewise, connections from OVP, UVLO and ADJ are also critical to optimize accuracy.

#### ADJUSTING THE HS COMPARATOR REVERSE VOLTAGE THRESHOLD

The ISL6146 allows adjustment of the HS Comparator reverse voltage detection threshold (VR Vth), the difference in  $V_{OUT}$  -  $V_{IN}$ .

There are two valid ADJ pin configurations:

1. ADJ connected to  $V_{OUT}$ : This makes the HS comparator threshold equal to the intrinsic error in the HS comparator input. This is the default condition and the most likely used configuration.
2. A single resistor is connected from ADJ pin to ground: Making the HS comparator threshold =  $V_{OUT} - 4k/R_{ADJ}$ .

So, for a 100k $\Omega$   $R_{EXT}$ , HS Comparator threshold = 40mV below  $V_{OUT}$  and for a 5k $\Omega$   $R_{EXT}$  HS comparator threshold = ~800mV below  $V_{OUT}$ .

The recommended resistor range is 5k $\Omega$  to 100k $\Omega$  for this voltage adjustment.

At power-up, the HS comparator threshold is default set to the internal device error first, and then released to the user programmed threshold after the related circuits are ready. It takes ~20 $\mu$ s for the circuit to switch from the default setting to the user programmed threshold after a POR startup.

The current out of the ADJ pin with a resistor to GND is equal to  $0.4V/R_{EXT}$ .

#### BACK-TO-BACK FET CONFIGURATION

When using the back-to-back FET configuration, the FET choice must be such that the voltage across both FETs at full current loading be less than the minimum forward voltage fault threshold of 400mV to avoid unintended fault notification.

In this configuration, it may be tempting to use the enable inputs to force a path by switching between the two as opposed to having both paths on, and having the higher voltage source provide current. The problem with that is the timing of the FETs on and off, so that excessive  $V_{OUT}$  voltage droop is not introduced if the turn-off happens faster, or before the (or a slower) turn-on momentarily leaves the load with an inadequate power connection.

### Typical Applications Circuits

There are four basic configurations that the ISL6146 can be used in:

1. For voltages >3V where the BIAS and  $V_{IN}$  are common
2. For a very low OR-ing voltage, <3V operation, BIAS >3V
3. For a voltage window compliant operation and,
4. For a signaled operation where the current path is controlled by an input signal or minimum voltage condition.

Each of these configurations can be tailored for the High Speed Comparator (HSCOMP) reverse threshold via the ADJ input being connected either to  $V_{OUT}$  or to GND via a resistor as previously explained. Additionally, the voltage window is adjustable for both a minimum and maximum operating voltage via the UVLO and OVP inputs and a resistor divider also explained earlier. Also, soft-start and turn-on and turn-off characteristics can be tailored to suit.

The three evaluation platforms provided demonstrate the four basic configurations and provide for the additional tailoring of the various performance characteristics.

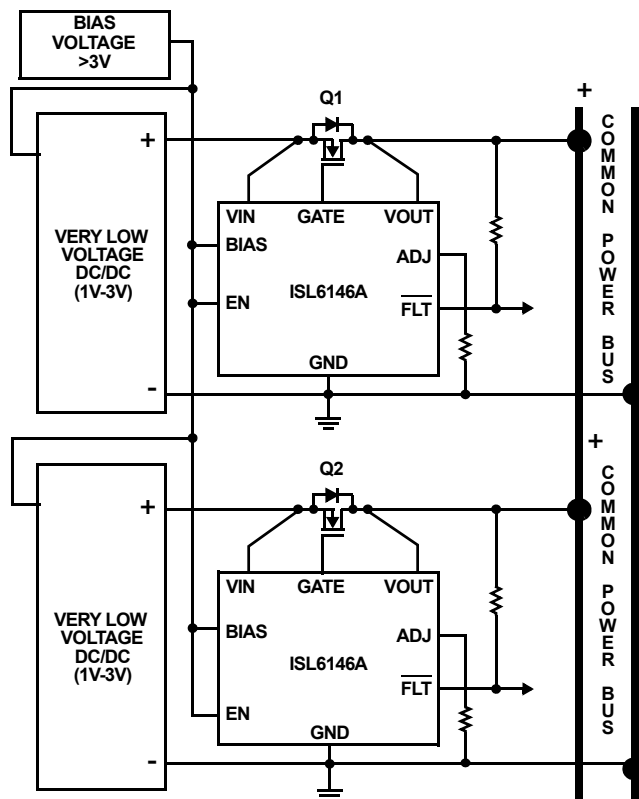


FIGURE 47. LOW VOLTAGE APPLICATION DIAGRAM

The circuit shown in [Figure 1](#) on page 1 is the basic circuit used for OR-ing voltages >3V to 20V.

The ISL6146A application shown in [Figure 47](#) is the configuration for OR-ing very low voltages of 1V to 3V. Additionally, this application shows the utilization of the ADJ input with a single resistor tied to GND. This provides the user a programmable level of  $V_{OUT} > V_{IN}$  before the High Speed (HS) Comparator is activated and the GATE output is pulled down to allow for normal voltage fluctuations in the system.

Notice that in both of these circuits, the EN or  $\overline{EN}$  inputs are defaulted to enabled and have no current path on/off control. Failure to do so correctly will result in only body diode conduction and a resulting fault indication.

The  $V_{IN}$  and  $V_{OUT}$  to FET and GND to ADJ connections are drawn to emphasize the Kelvin connection necessary to correctly monitor the voltage across the FET, and for the VR Vth monitor to eliminate any stray resistance effects.

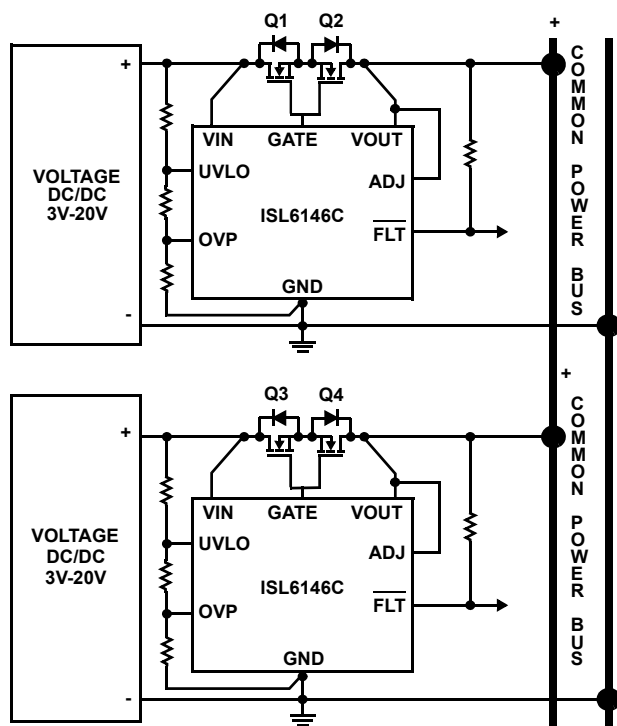


FIGURE 48. TYPICAL ISL6146C APPLICATION DIAGRAM

The ISL6146C application shown in [Figure 48](#) is limited to the 3V to 20V  $V_{IN}$  range and must implement the back-to-back FET configuration to utilize the UVLO and OVP inputs and capabilities. As the  $V_{IN}$  voltage rises above the minimum programmed voltage, the related OR-ing FETs will turn on and stay on until either the minimum voltage requirement is no longer met or the  $V_{IN}$  voltage exceeds its programmed maximum. The minimum and maximum programmed voltage levels are done with the resistor divider on the UVLO and OVP pins. These levels should be programmed to take into account conduction path losses to the load in addition to the IC operational constraints.

When using the back-to-back FET configuration, the user must choose FETs to ensure  $(2r_{DS(ON)} + PCB\ IR) I_{LOAD} < 0.5V$  to avoid tripping the  $V_{IN} - V_{OUT} > 0.5V$  when ON fault.

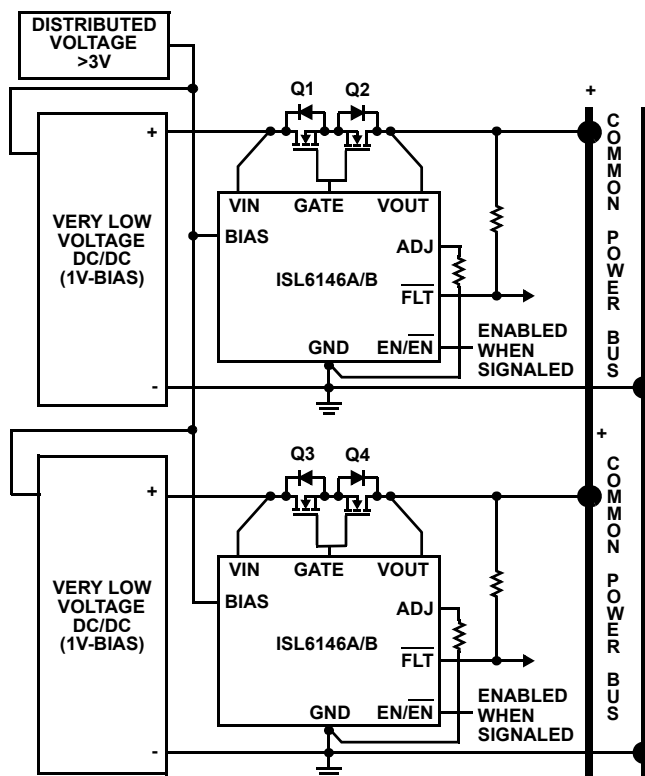


FIGURE 49. CONTROLLED ON/OFF APPLICATION DIAGRAM

The application diagram in [Figure 49](#) shows the ISL6146A or ISL6146B utilizing the EN or  $\overline{EN}$  pin as a signalled input to open or close the conduction path from power supply to load. This feature can be implemented on OR-ing 1V to 20V but is shown for OR-ing <3V.

The enable input signaling can be simultaneous across the N+1 number of ISL6146s used.

Although not needed for thermal relief, connect the DFN EPAD to GND.

## SWITCHOVER CIRCUITS

Switchover applications are different than OR-ing applications in that the former are looking for the presence of, or a condition of, a preferred supply in order to switch to it. Whereas true OR-ing consists of a redundant N+1 configuration with no preferred source.

The following 2 circuits are simple single ISL6146 switchover circuits optimized for situations particular to the  $V_{BATT}$  and  $V_{EXT}$  voltages relative to each other. [Figure 50](#) shows an ISL6146B switchover circuit where  $V_{EXT}$ , when present, is the preferred source and  $V_{BATT}$  could be lesser or greater than  $V_{EXT}$ . This circuit senses the presence of the preferred voltage supply to a programmable threshold level that, when exceeded,  $V_{EXT}$  is passed to the output as  $V_{BATT}$  is disconnected from the output.

$R_1$  and  $R_2$  program the  $V_{EXT}$  level that must be preset for the preferred voltage to be passed to the output.

Q3 is necessary if  $V_{BATT}$  can ever exceed  $V_{EXT}$  to prevent current from flowing into  $V_{EXT}$  when present. The body diode of Q3 prevents that when Q1 is on regardless of the  $V_{BATT}$  voltage. The

ISL6146 bias is pulled from the common drain node to ensure an always adequate bias from either source when the other is absent.

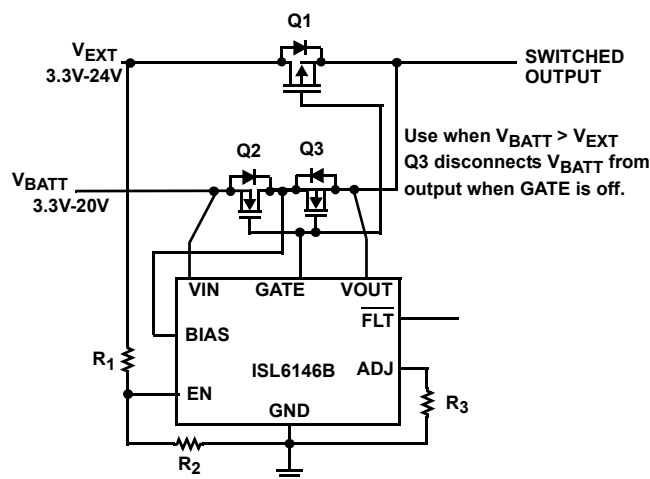


FIGURE 50. ISL6146B EXTERNAL SWITCHOVER SCHEMATIC

Figure 51 shows operational scope shots of the above circuit.

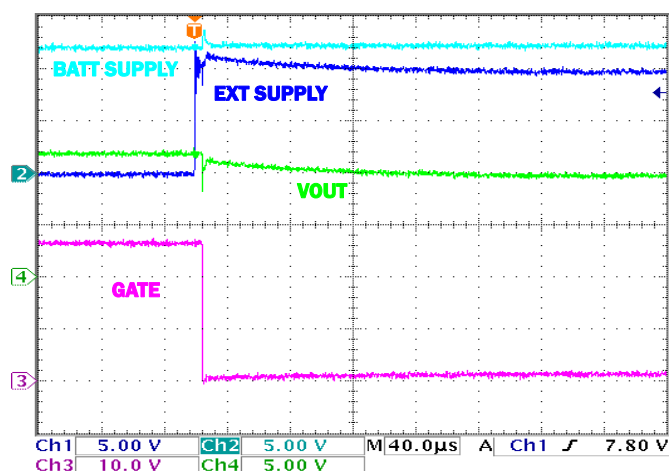


FIGURE 51. EXTERNAL SUPPLY < BATT SUPPLY CONNECTED

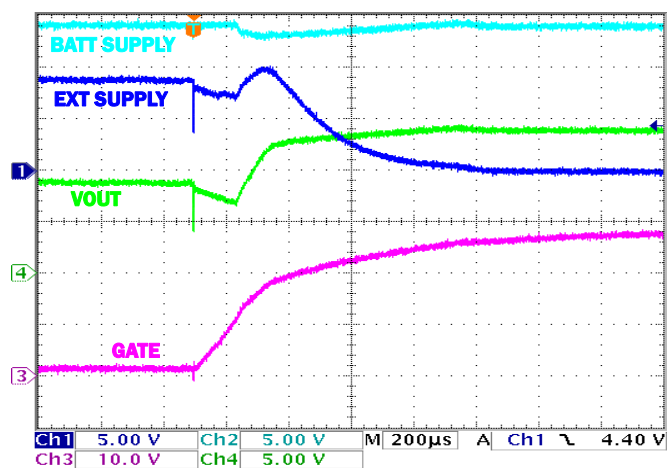


FIGURE 52. EXTERNAL SUPPLY < BATT SUPPLY DISCONNECTED

All of the scope shots were taken with a 5A load and 100μF of bulk load capacitance.

Figure 52 is a ISL6146A switchover circuit to use where the preferred  $V_{EXT}$  source is always greater than the  $V_{BATT}$ . Because this is so, there is no need for a 3rd FET for blocking as in Figure 50. Additionally, the preferred  $V_{EXT}$  source when present or at a programmed minimum threshold voltage via  $R_1$  and  $R_2$  divider, will turn on Q2/turn-off Q1 but when absent or not minimally adequate, will do the opposite. In this circuit, with the ISL6146A not connected to the battery, and thus no constant  $I_{VIN}$  load on it, which allows for longer battery life.

Bias voltage is pulled from the common output to ensure an always adequate IC bias from either source.

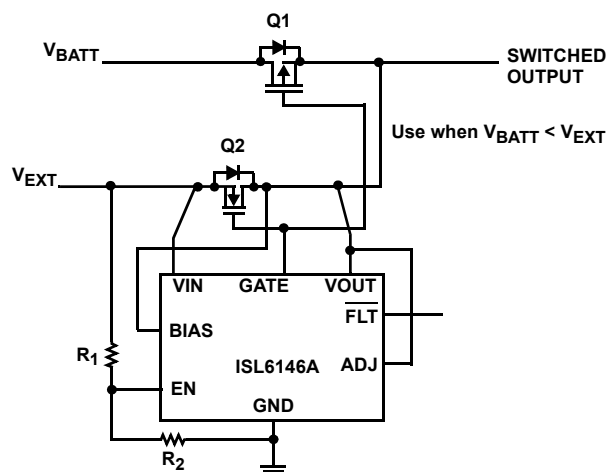


FIGURE 53. ISL6146A EXTERNAL SWITCHOVER SCHEMATIC

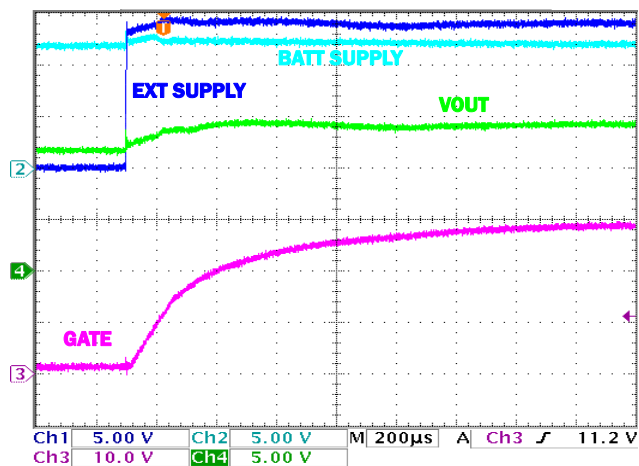


FIGURE 54. EXTERNAL SUPPLY > BATT SUPPLY CONNECTED

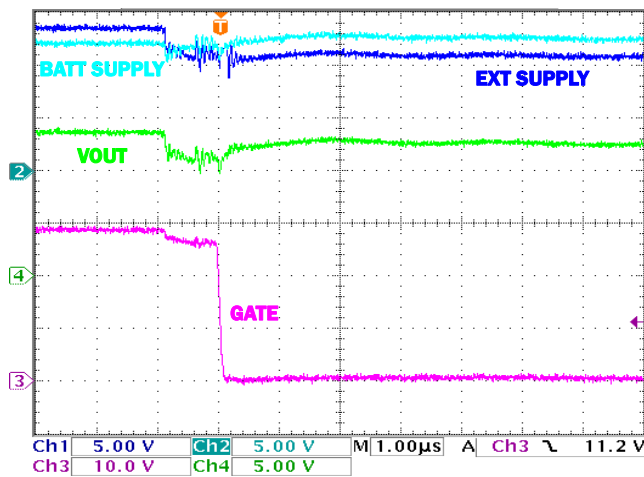


FIGURE 55. EXTERNAL SUPPLY &gt; BATT SUPPLY DISCONNECTED

## ISL6146 Evaluation Platforms

### Description and Use of the Evaluation Boards

The three ISL6146 evaluation boards are used to demonstrate the four application configurations discussed earlier. All the boards have ADJ shorted to VOUT with the PCB layout having the component footprints to insert a resistor of choice between ADJ and GND to adjust the HS COMP Vth. Likewise, the VIN is connected to BIAS but these can be separated to provide an adequate BIAS voltage when OR-ing <3V supplies or if providing a separate from VIN voltage to BIAS.

The **ISL6146AEVAL1Z** is configured to have a 8.5V minimum turn-on threshold with a 1.2V hysteresis.

The **ISL6146BEVAL1Z** is configured as a minimally featured maximum performance OR-ing FET controller for 3V to 20V.

The **ISL6146CEVAL1Z** is configured to operate with a 10.8V lower turn on threshold and 14.9V upper turn-off threshold.

All three boards are equipped with 50A capable FETs for high current evaluations and with a minimum of  $V_{IN}$  and  $V_{OUT}$  bulk capacitance likely to be found in any power system design.

After determining the BIAS source along with  $V_{IN}$  voltage criteria and configuring the evaluation board if necessary, for the application to be evaluated the board is ready for power.

Apply the BIAS voltage first (via the test points labeled BIAS), if separate from  $V_{IN}$ , then the  $V_{IN}$  voltage. Monitor the provided test points for device performance with current loads up to 50A.

Figures 56 through 61 illustrate the three ISL6146 evaluation boards for the three typical applications in photograph and schematic form.

There are also 2 mini development boards named ISL6146DEVAL1Z and ISL6146EEVAL1Z. These boards are provided as a matching pair of either the ISL6146D or ISL6146E part type directly from the website or with either the ISL6146A or ISL6146B installed from the factory (contact support if desired). The small size (1" x 0.5") is suitable for adding into an existing circuit using another OR-ing FET controller. These small and simple boards have only the necessary components for its implementation utilizing the already present MOSFET(s) in the circuit it is being added to.

The mini evaluation circuit is designed to give the user the flexibility in either defaulting or signaling the enable ON or to use a  $V_{IN}$  voltage threshold to turn-on the IC function. Provided are access to the IC VIN, GATE and VOUT pins for best practices connections to the MOSFET(s) along with adjustable HS Vth via the ADJ pin and the  $\overline{\text{FAULT}}$  output.

The mini evaluation circuit is documented in Figures 62, 63 and Table 2.

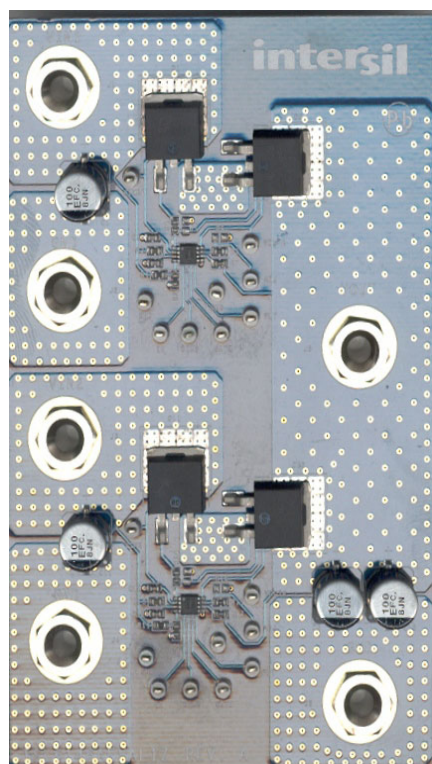


FIGURE 56. ISL6146AEVAL1Z

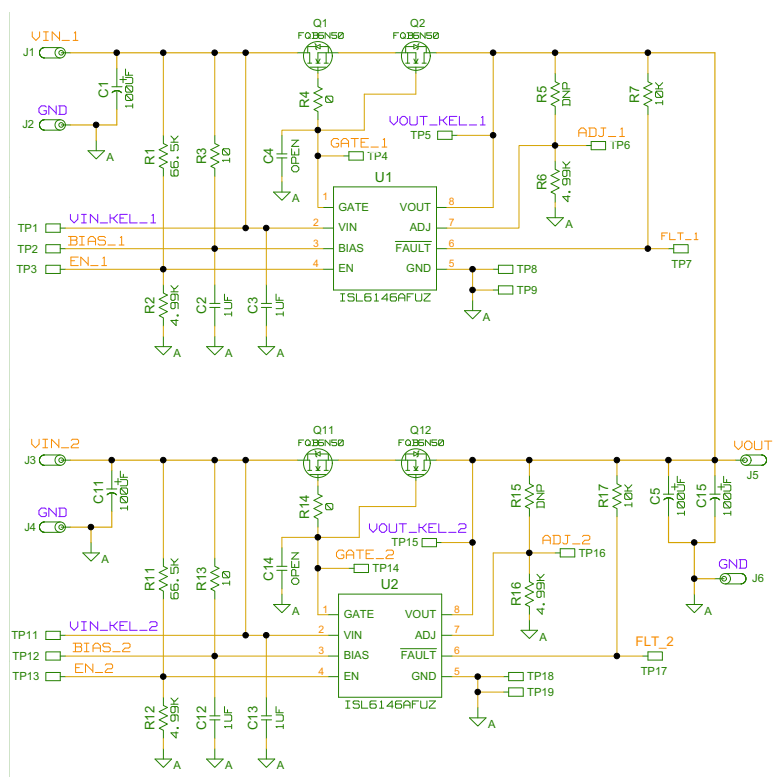


FIGURE 57. ISL6146AEVAL1Z SCHEMATIC

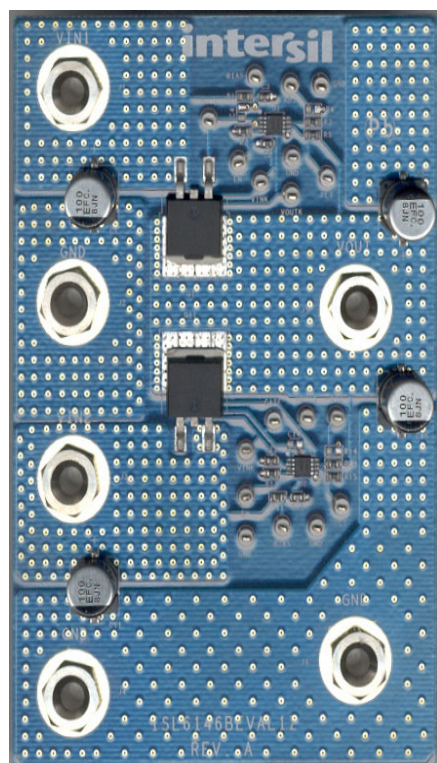


FIGURE 58. ISL6146BEVAL1Z

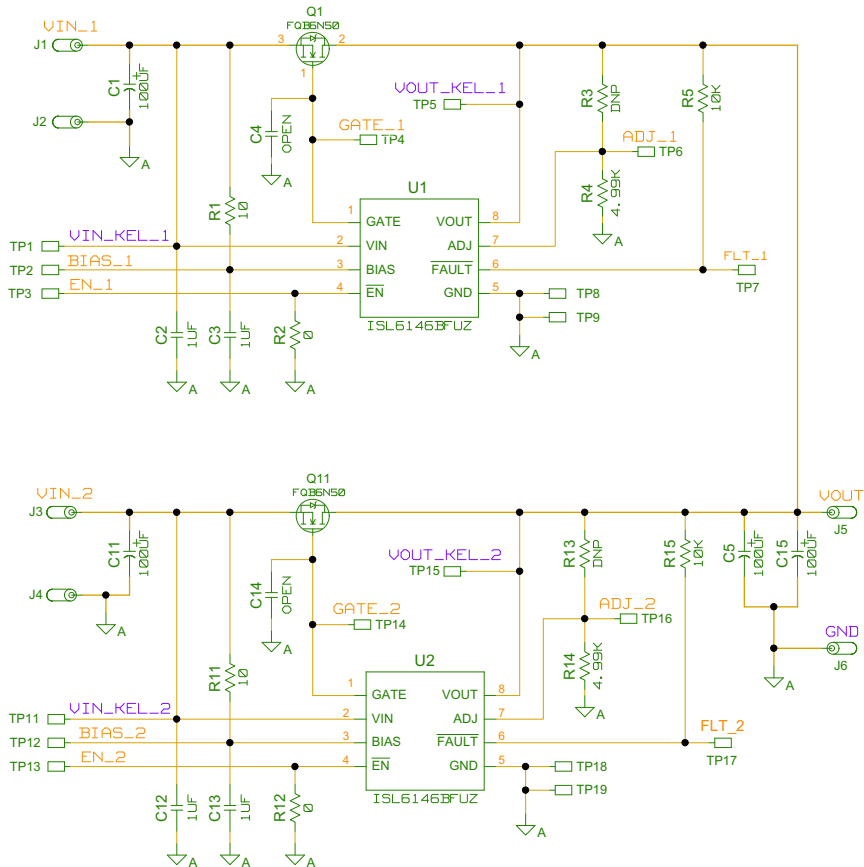


FIGURE 59. ISL6146BEVAL1Z SCHEMATIC

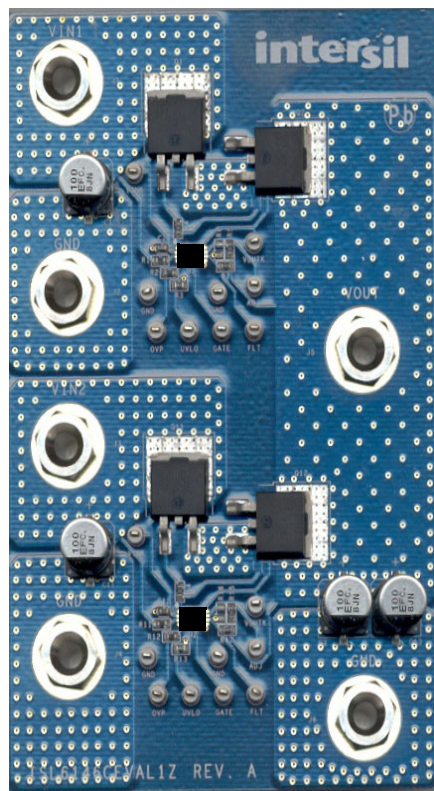


FIGURE 60. ISL6146CEVAL1Z

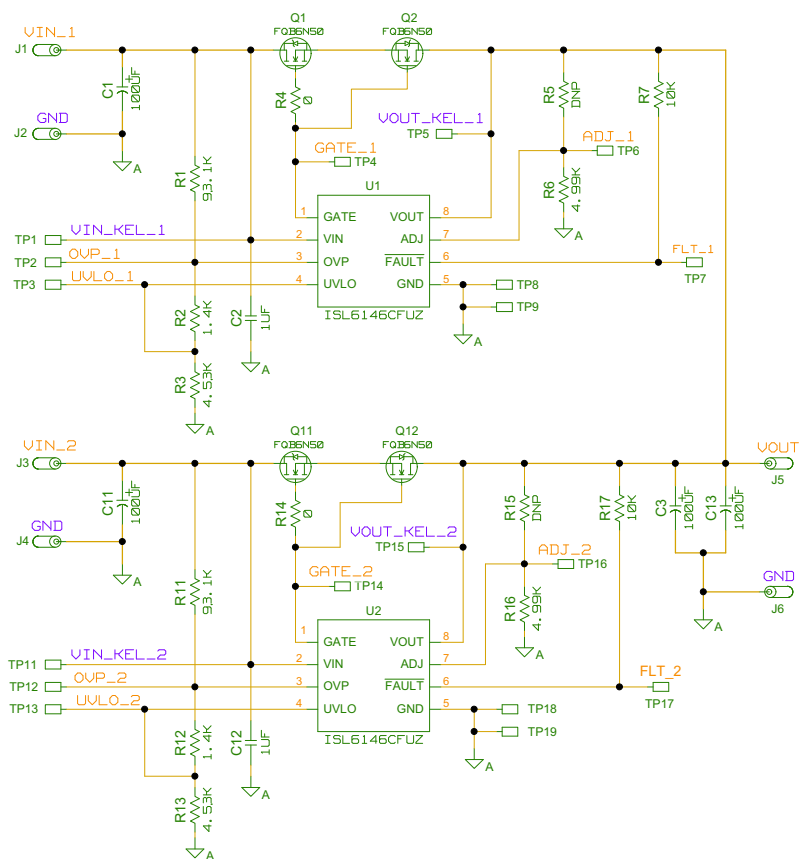
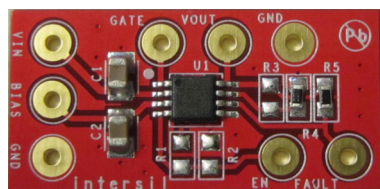


FIGURE 61. ISL6146CEVAL1Z SCHEMATIC



Dimensions are  
1" x 0.5" (25.4mm x 12.7mm)

FIGURE 62. ISL6146DEVAL1Z

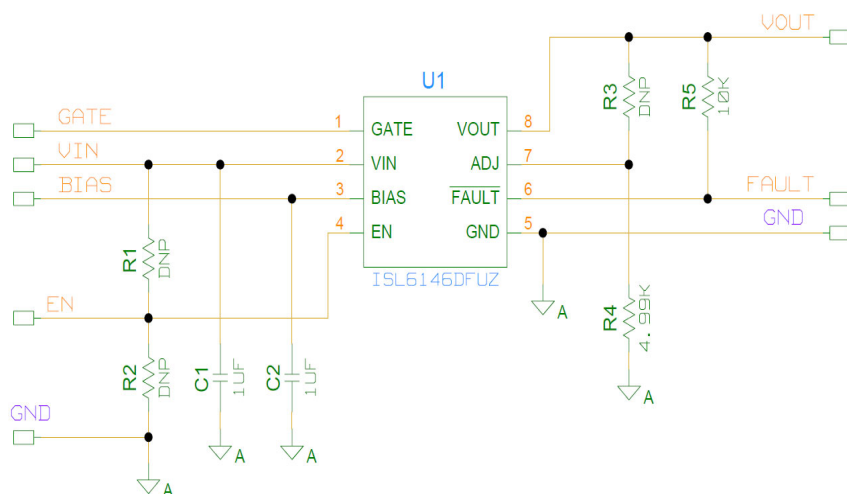


FIGURE 63. ISL6146DEVAL1Z SCHEMATIC (Mini-eval)

TABLE 2. ISL6146x EVALZ BOM

| REFERENCE DESIGNATOR  | VALUE          | DESCRIPTION                    | MANUFACTURER | PART NUMBER |
|-----------------------|----------------|--------------------------------|--------------|-------------|
| <b>ISL6146AEVAL1Z</b> |                |                                |              |             |
| U1, U2                |                | ISL6146A OR-ing FET Controller | Intersil     | ISL6146AFUZ |
| Q1, Q2, Q11, Q12      |                | 30V, 50A FET                   | Various      |             |
| R1, 11                | 66.5k $\Omega$ | RES, SMD, 0603, 1%             | Generic      |             |
| R2, R12, R6, R16      | 4.99k $\Omega$ | RES, SMD, 0603, 1%             | Generic      |             |
| R3, R13               | 10 $\Omega$    | RES, SMD, 0603, 1%             | Generic      |             |
| R4, R14               | 0 $\Omega$     | RES, SMD, 0603, 1%             | Generic      |             |
| R5, R15               | DNP            | RES, SMD, 0603, 1%             | Generic      |             |
| R7, R17               | 10k $\Omega$   | RES, SMD, 0603, 1%             | Generic      |             |
| C1, C11, C5, C15      | 100 $\mu$ F    | Alum. Elect SMD Cap            | Generic      |             |
| C2, C3, C12, C13      | 1 $\mu$ F      | CAP, SMD, 0603, 50V, 10%       | Generic      |             |
| C4, C14               | DNP            | CAP, SMD, 0603, 50V, 10%       | Generic      |             |
| TPx                   |                | Test Point                     | Generic      |             |
| Jx                    |                | Banana Jack                    | Generic      |             |
| <b>ISL6146BEVAL1Z</b> |                |                                |              |             |
| U1, U2                |                | ISL6146B OR-ing FET Controller | Intersil     | ISL6146BFUZ |
| Q1, Q11               |                | 30V, 50A FET                   | Various      |             |
| R4, R14               | 4.99k $\Omega$ | RES, SMD, 0603, 1%             | Generic      |             |
| R1, R10               | 10 $\Omega$    | RES, SMD, 0603, 1%             | Generic      |             |
| R2, R12               | 0 $\Omega$     | RES, SMD, 0603, 1%             | Generic      |             |
| R3, R13               | DNP            | RES, SMD, 0603, 1%             | Generic      |             |
| R5, R15               | 10k $\Omega$   | RES, SMD, 0603, 1%             | Generic      |             |
| C1, C11, C5, C15      | 100 $\mu$ F    | Alum. Elect SMD Cap            | Generic      |             |
| C2, C3, C12, C13      | 1 $\mu$ F      | CAP, SMD, 0603, 50V, 10%       | Generic      |             |
| C4, C14               | DNP            | CAP, SMD, 0603, 50V, 10%       | Generic      |             |
| TPx                   |                | Test Point                     | Generic      |             |
| Jx                    |                | Banana Jack                    | Generic      |             |
| <b>ISL6146CEVAL1Z</b> |                |                                |              |             |
| U1, U2                |                | ISL6146C OR-ing FET Controller | Intersil     | ISL6146CFUZ |
| Q1, Q2, Q11, Q12      |                | 30V, 50A FET                   | Various      |             |
| R1, 11                | 93.1k $\Omega$ | RES, SMD, 0603, 1%             | Generic      |             |
| R2, R12               | 1.4k $\Omega$  | RES, SMD, 0603, 1%             | Generic      |             |
| R3, R13               | 4.53k $\Omega$ | RES, SMD, 0603, 1%             | Generic      |             |
| R4, R14               | 0 $\Omega$     | RES, SMD, 0603, 1%             | Generic      |             |
| R5, R15               | DNP            | RES, SMD, 0603, 1%             | Generic      |             |
| R6, R16               | 4.99k $\Omega$ | RES, SMD, 0603, 1%             | Generic      |             |
| R7, R17               | 10k $\Omega$   | RES, SMD, 0603, 1%             | Generic      |             |
| C1, C11, C3, C13      | 100 $\mu$ F    | Alum. Elect SMD Cap            | Generic      |             |
| C2, C12               | 1 $\mu$ F      | CAP, SMD, 0603, 50V, 10%       | Generic      |             |
| TPx                   |                | Test Point                     | Generic      |             |
| Jx                    |                | Banana Jack                    | Generic      |             |

TABLE 2. ISL6146xEVALZ BOM (Continued)

| REFERENCE DESIGNATOR  | VALUE          | DESCRIPTION                    | MANUFACTURER | PART NUMBER |
|-----------------------|----------------|--------------------------------|--------------|-------------|
| <b>ISL6146DEVAL1Z</b> |                |                                |              |             |
| U1                    |                | ISL6146D OR-ing FET Controller | Intersil     | ISL6146DFUZ |
| R1, R2, R3            | DNP            | RES, SMD, 0603, 1%             | Generic      |             |
| R4                    | 4.99k $\Omega$ | RES, SMD, 0603, 1%             | Generic      |             |
| R5                    | 10k $\Omega$   | RES, SMD, 0603, 1%             | Generic      |             |
| C1, C2                | 1 $\mu$ F      | CAP, SMD, 0603, 50V, 10%       | Generic      |             |
| <b>ISL6146EEVAL1Z</b> |                |                                |              |             |
| U1                    |                | ISL6146E OR-ing FET Controller | Intersil     | ISL6146EFUZ |
| R1, R2, R3            | DNP            | RES, SMD, 0603, 1%             | Generic      |             |
| R4                    | 4.99k $\Omega$ | RES, SMD, 0603, 1%             | Generic      |             |
| R5                    | 10k $\Omega$   | RES, SMD, 0603, 1%             | Generic      |             |
| C1, C2                | 1 $\mu$ F      | CAP, SMD, 0603, 50V, 10%       | Generic      |             |

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## Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

| DATE               | REVISION | CHANGE                                                                                                                                                                                                                                                                                                                                              |
|--------------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| August 17, 2015    | FN7667.5 | Added a capacitor to each device in Figure 1 on page 1.<br>Updated the Ordering Information table on page 5.<br>Updated POD "L8.3x3J" on page 27 to the latest revision.                                                                                                                                                                            |
| April 3, 2013      | FN7667.4 | Added ISL6146DEVAL1Z and ISL6146EEVAL1Z related information. Figures 62 and 63. Corrected labels in Figure 61.                                                                                                                                                                                                                                      |
| September 27, 2012 | FN7667.3 | Added tape and reel parts to Ordering Information table for ISL6146A/B/C/D/E products.<br>Thermal Information - removed Pb-Free Reflow link                                                                                                                                                                                                         |
| June 18, 2012      | FN7667.2 | Added ISL6146D and ISL6146E. References to these products added throughout the datasheet. Added Figures 45 and 46 to illustrate the fault differences between ISL6146A/B and ISL6146D/E. Moved Figure 50 and revised the related text on page 20 before the evaluation board section. Added Figures 51 - 55 and related text on page 20 to page 21. |
| February 27, 2012  | FN7667.1 | Removed note "MSOP packaged parts to be released soon" from "Ordering Information" on page 5. Added Figures 42 and 43 on page 15.                                                                                                                                                                                                                   |
| December 16, 2011  | FN7667.0 | Initial Release                                                                                                                                                                                                                                                                                                                                     |

## About Intersil

Intersil Corporation is a leading provider of innovative power management and precision analog solutions. The company's products address some of the largest markets within the industrial and infrastructure, mobile computing and high-end consumer markets.

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You may report errors or suggestions for improving this datasheet by visiting [www.intersil.com/ask](http://www.intersil.com/ask).

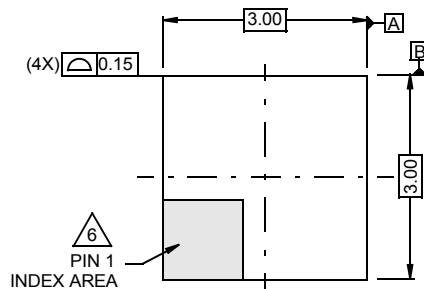
Reliability reports are also available from our website at [www.intersil.com/support](http://www.intersil.com/support)

# Package Outline Drawing

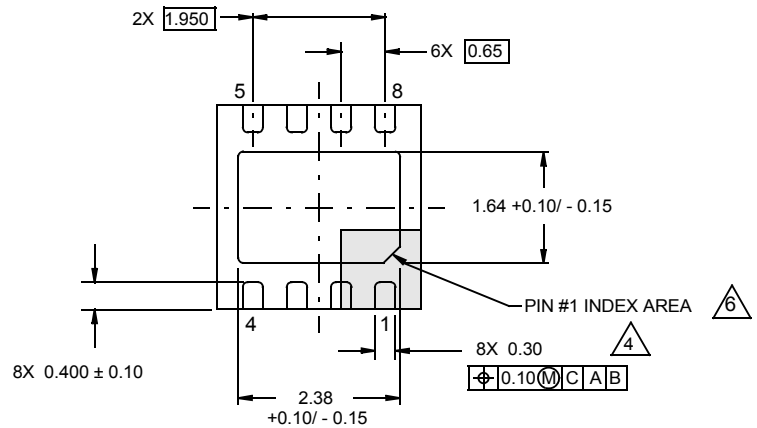
## L8.3x3J

8 LEAD DUAL FLAT NO-LEAD PLASTIC PACKAGE

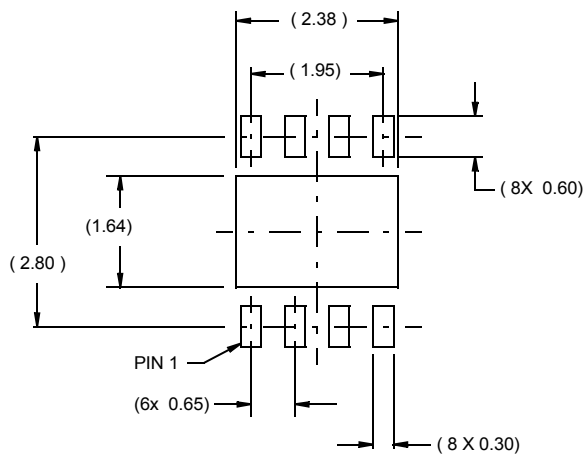
Rev 1 3/15



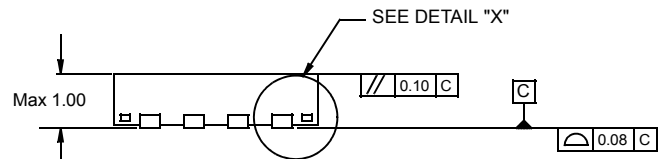
**TOP VIEW**



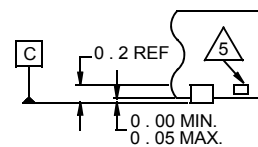
**BOTTOM VIEW**



**TYPICAL RECOMMENDED LAND PATTERN**



**SIDE VIEW**



**DETAIL "X"**

### NOTES:

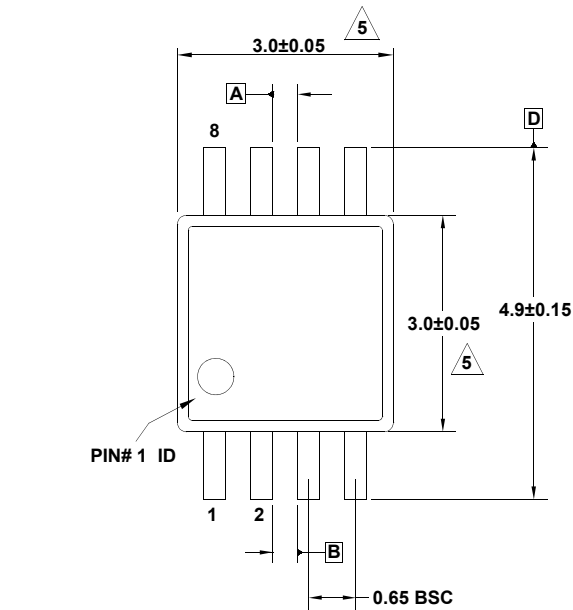
- Dimensions are in millimeters.  
Dimensions in ( ) for Reference Only.
- Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
- Unless otherwise specified, tolerance : Decimal  $\pm 0.05$
- △4. Dimension applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
- △5. Tiebar shown (if present) is a non-functional feature and may be located on any of the 4 sides (or ends).
- △6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.

# Package Outline Drawing

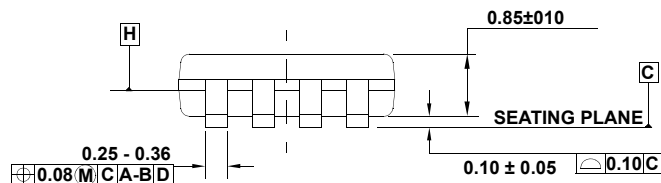
## M8.118

8 LEAD MINI SMALL OUTLINE PLASTIC PACKAGE

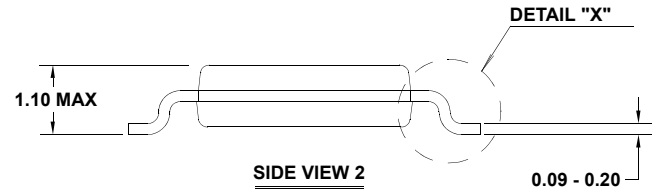
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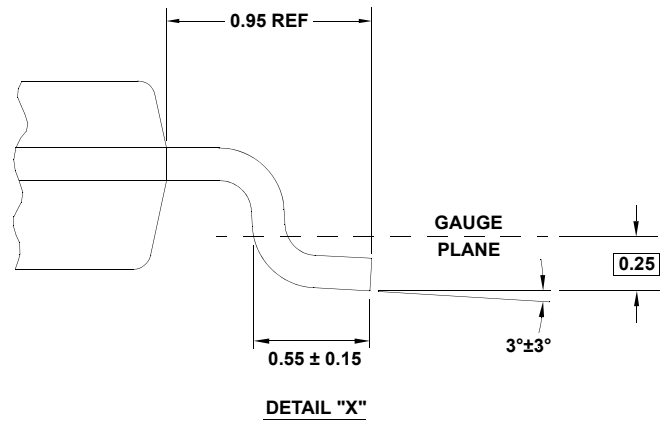
TOP VIEW



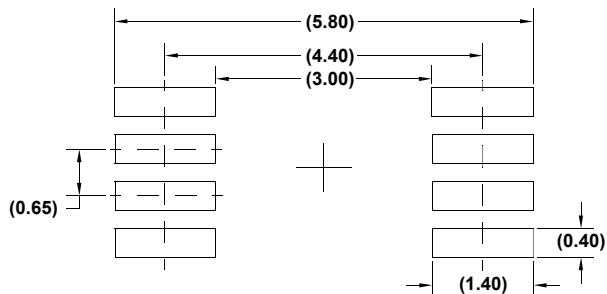
SIDE VIEW 1



SIDE VIEW 2



DETAIL "X"



TYPICAL RECOMMENDED LAND PATTERN

### NOTES:

1. Dimensions are in millimeters.
2. Dimensioning and tolerancing conform to JEDEC MO-187-AA and AMSEY14.5m-1994.
3. Plastic or metal protrusions of  $0.15\text{mm}$  max per side are not included.
4. Plastic interlead protrusions of  $0.15\text{mm}$  max per side are not included.

5. Dimensions are measured at Datum Plane "H".

6. Dimensions in ( ) are for reference only.